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# (54) MATERIALS FOR ORGANIC ELECTROLUMINESCENT DEVICES

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See application file for complete search history.

#### (56) References Cited

#### U.S. PATENT DOCUMENTS

4,539,507	A	9/1985	VanSlyke et al.
5,151,629	A	9/1992	VanSlyke
5,840,217	A	11/1998	Lupo et al.
5,935,721	Α	8/1999	Shi et al.
5,968,675	A *	10/1999	Tamano et al 428/690
6,458,909	B1	10/2002	Spreitzer et al.
6,534,199	B1	3/2003	Hosokawa et al.
6,713,192	B2	3/2004	Fukuoka et al.
6,878,469	B2*	4/2005	Yoon et al 428/690
6,908,783	B1	6/2005	Kuehl et al.
7,485,733	B2	2/2009	Kim et al.
7,604,874	B2	10/2009	Kim et al.
2002/0132134	A1*	9/2002	Hu et al 428/690
2004/0067387	A1*	4/2004	Kim et al 428/690
2004/0214035	A1*	10/2004	Ikeda et al 428/690
2005/0040390	A1	2/2005	Pfeiffer et al.
2005/0064233	A1	3/2005	Matsuura et al.
2005/0214565	A1	9/2005	Ikeda et al.
2005/0233165	A1	10/2005	Ido et al.
2006/0033421	A1	2/2006	Matsuura et al.
2006/0035109	A1*	2/2006	Arakane et al 428/690
2006/0040131	A1*	2/2006	Klubek et al 428/690
2006/0043858	A1	3/2006	Ikeda et al.
2006/0063027	A1	3/2006	Vestweber et al.
2006/0134456	A1	6/2006	Ikeda et al.
2006/0175958	A1	8/2006	Gerhard et al.
2006/0220004	A1	10/2006	Stossel et al.
2006/0269782	A1*	11/2006	Liao et al 428/690
2007/0055085	A1*	3/2007	Kubota et al 585/26
2007/0134512	A1*	6/2007	Klubek et al 428/690
2007/0164273	A1	7/2007	Gerhard et al.
2007/0170419	$\mathbf{A}1$	7/2007	Gerhard et al.
2007/0200490	A1	8/2007	Kawamura et al.
2008/0125609	A1	5/2008	Vestweber et al.
		(Con	tinued)

#### FOREIGN PATENT DOCUMENTS

CN	1362464 A	8/2002
CN	1556803 A	12/2004
CN		tinued)

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#### (57) ABSTRACT

The present invention relates to anthracene derivatives, to the use thereof in organic electroluminescent devices, and to organic electroluminescent devices comprising these compounds.

#### 14 Claims, No Drawings

# US **8,999,521 B2**Page 2

(56)	References Cited	WO	WO-03/087023 A1	10/2003
		WO	WO-03/095445 A1	11/2003
	U.S. PATENT DOCUMENTS	WO	WO-2004/013073 A1	2/2004
		WO	WO-2004/016575 A1	2/2004
2008/0	0145698 A1 6/2008 Heil et al.	WO	WO-2004/018587 A1	3/2004
	0182129 A1* 7/2008 Klubek et al	WO	WO-2004/018588 A1	3/2004
2000/0	7182129 A1 7/2008 Klubck et al 428/704	WO	WO-2004/058911 A2	7/2004
	EODELON DAMENTE DOCUMENTO	WO	WO-2004/081017 A1	9/2004
	FOREIGN PATENT DOCUMENTS	WO	WO-2005/011013 A1	2/2005
		WO	WO-2005054162 A1	6/2005
EP	0676461 A2 10/1995	WO	WO-2005/084081 A1	9/2005
EP	1596445 A1 11/2005	WO	WO-2005/084082 A1	9/2005
EP	1734038 A1 12/2006	WO	WO-2005/097756 A1	10/2005
JР	2005515233 A 5/2005	WO	WO-2005097756 A1	10/2005
JР	2005531552 A 10/2005	WO	WO-2006/000388 A1	1/2006
KR	20040028954 A 4/2004	WO	WO-2006/000389 A1	1/2006
WO	WO-98/27136 A1 6/1998	WO	WO-2006/048268 A1	5/2006
WO	WO-01/21729 A1 3/2001	WO	WO-2006/058737 A1	6/2006
WO	WO-01/76323 A1 10/2001	WO	WO-2006/117052 A1	11/2006
WO	WO-03/060956 A2 7/2003			11.2000
WO	WO-03/070822 A2 8/2003	* cite	d by examiner	

# MATERIALS FOR ORGANIC ELECTROLUMINESCENT DEVICES

#### RELATED APPLICATIONS

This application is a national stage application (under 35 U.S.C. §371) of PCT/EP2007/001732, filed Feb. 28, 2007, which claims benefit of German application 102006013802.3, filed Mar. 24, 2006.

The present invention relates to novel anthracene derivatives, to the use thereof in organic electroluminescent devices, and to organic electroluminescent devices comprising these compounds.

Organic semiconductors are used as functional materials in a number of different applications which can be ascribed to the electronics industry in the broadest sense. The general structure of organic electroluminescent devices which are capable of the emission of light in the visible spectral region is described, for example, in U.S. Pat. No. 4,539,507, U.S. 20 Pat. No. 5,151,629, EP 0676461 and WO 98/27136.

However, these devices still exhibit considerable problems which require urgent improvement for use in high-quality full-colour displays:

- The efficiency, colour and lifetime of the organic electroluminescent devices are still inadequate for high-quality applications.
- 2. The compounds used frequently do not have a sufficiently high glass-transition temperature.
- 3. The redox stability (stability to holes and electrons) of the compounds used to date is still inadequate.
- The charge-carrier mobility, in particular the electron mobility, is inadequate.
- 5. The operating voltage should be reduced still further, in  $_{\rm 35}$  particular for mobile applications.

The closest prior art which may be mentioned is the use of various condensed aromatic compounds, in particular anthracene or pyrene derivatives, as host materials, in particular for blue-emitting electroluminescent devices. 9,10-Bis(2-10) naphthyl)anthracene is known as host material in accordance with the prior art (U.S. Pat. No. 5,935,721). Further anthracene derivatives which are suitable as host materials are described in WO 01/076323, in WO 01/021729, in WO 04/013073, in WO 04/018588, in WO 03/087023 or in WO 04/018587. Host materials based on aryl-substituted pyrenes and chrysenes are described in WO 04/016575. WO 03/095445 and CN 1362464 describe 9,10-bis(1-naphthyl) anthracene derivatives for use in OLEDs.

The object of the present invention was to provide compounds having improved properties, in particular improved host materials.

Surprisingly, it has been found that organic electroluminescent devices which comprise anthracene derivatives which are substituted in the 9,10-position by ortho-substituted phenyl groups and which are furthermore substituted in the 2,6-position by aryl or heteroaryl groups have significant improvements compared with the prior art. The present invention therefore relates to these compounds and to the use thereof in OLEDs.

WO 03/060956 and WO 05/097756 disclose anthracene derivatives which are substituted in the 9,10-position by ortho-biphenyl and which are furthermore substituted in the 2,6-position by aryl groups which contain benzimidazole. 65 The positive effect of these compounds is attributed to the presence of the benzimidazole groups.

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The invention relates to compounds of the formula (1)

Formula (1)  $\begin{bmatrix} R^{1} \end{bmatrix}_{n}$   $\begin{bmatrix} R^{1} \end{bmatrix}_{p}$   $\begin{bmatrix} R^{1} \end{bmatrix}_{n}$   $\begin{bmatrix} R^{1} \end{bmatrix}_{n}$ 

where the following applies to the symbols and indices used: Ar is on each occurrence, identically or differently, an aromatic or heteroaromatic ring system having 6 to 30 aromatic ring atoms, which may be substituted by one or more radicals R<sup>1</sup>:

R, R<sup>1</sup> are, identically or differently on each occurrence, F, Cl, Br, I, CN,  $N(Ar^1)_2$ ,  $C(=O)Ar^1$ ,  $P(Ar^1)_2$ ,  $P(-O)(Ar^1)_2$ , Si(R<sup>2</sup>)<sub>3</sub>, NO<sub>2</sub>, a straight-chain alkyl, alkoxy or thioalkoxy group having 1 to 40 C atoms or a branched or cyclic alkyl, alkoxy or thioalkoxy group having 3 to 40 C atoms, each of which may be substituted by one or more radicals R<sup>2</sup>, where one or more non-adjacent CH2 groups may be replaced by  $-R^2C = CR^2$ ,  $-C = C - Si(R^2)_2$ ,  $Ge(R^2)_2$ ,  $Sn(R^2)_2$ , C=, C=S, C=Se, C= $NR^2$ , O-, -S-, - $N(R^2)$ - or - $CONR^2$ - and where one or more H atoms may be replaced by F, Cl, Br, I, CN or NO<sub>2</sub>, or an aromatic or heteroaromatic ring system having 5 to 30 aromatic ring atoms, which may be substituted by one or more radicals R<sup>2</sup> or an aryloxy or heteroaryloxy group having 5 to 24 aromatic ring atoms, which may be substituted by one or more radicals R<sup>2</sup>, or a combination of two, three, four or five of these systems; adjacent substituents R and R<sup>1</sup> or adjacent substituents R<sup>1</sup> here may also form a mono- or polycyclic, aliphatic ring system with one another;

 $Ar^1$  is on each occurrence, identically or differently, an aromatic or heteroaromatic ring system having 5 to 30 aromatic ring atoms, which may be substituted by one or more non-aromatic radicals  $R^1$ ; two radicals  $Ar^1$  here may also be connected to one another by a single bond or an O, S,  $N(R^2)$  or  $C(R^2)_2$  group;

R<sup>2</sup> is on each occurrence, identically or differently, H or a hydrocarbon radical having 1 to 20 C atoms, which may be aliphatic or aromatic or a combination of aliphatic and aromatic and which may also be substituted by F; two or more radicals R<sup>2</sup> here may also form a mono- or polycyclic, aliphatic or aromatic ring system with one another;

55 n is, identically or differently on each occurrence, 0, 1, 2 or 3; p is, identically or differently on each occurrence, 0, 1, 2, 3 or

with the proviso that the substituents Ar are not substituted or unsubstituted benzimidazole and that no radicals R<sup>1</sup> which contain substituted or unsubstituted benzimidazole are bonded to the substituents Ar.

For the purposes of this invention, an aryl group or heteroaryl group is taken to mean an aromatic group or heteroaromatic group respectively having a common aromatic  $\pi$ -electron system. For the purposes of this invention, this may be a simple homo- or heterocycle, for example benzene, pyridine, etc., or it may be a condensed aryl or heteroaryl

group in which at least two aromatic or heteroaromatic rings, for example benzene rings, are "fused" to one another, i.e. are condensed onto one another by anellation, i.e. have at least one common edge and thus also a common aromatic  $\pi$ -electron system. These aryl or heteroaryl groups may be substituted or unsubstituted; any substituents present may likewise form further ring systems. Thus, for example, systems such as naphthalene, anthracene, phenanthrene, pyrene, etc., are to be regarded as acyl groups and quinoline, acridine, benzothiophene, carbazole, etc., are as heteroaryl groups for the purposes of this invention, while, for example, biphenyl, fluorene, spirobifluorene, etc., are not aryl groups since they involve separate aromatic electron systems.

For the purposes of this invention, an aromatic ring system contains 6 to 40 C atoms in the ring system. For the purposes of this invention, a heteroaromatic ring system contains 2 to 40 C atoms and at least one heteroatom in the ring system, with the proviso that the total number of C atoms and heteroatoms is at least 5. The heteroatoms are preferably selected from N, O and/or S. These aromatic and heteroaromatic ring systems may be substituted or unsubstituted; any substituents 20 present may likewise form further ring systems. For the purposes of this invention, an aromatic or heteroaromatic ring system is intended to be taken to mean a system which does not necessarily contain only aryl or heteroaryl groups, but instead in which a plurality of aryl or heteroaryl groups may 25 also be interrupted by a short non-aromatic unit (preferably less than 10% of the atoms other than H), such as, for example, an sp<sup>3</sup>-hybridised C, N or O atom. Thus, for example, systems such as 9,9'-spirobifluorene, fluorene, 9,9diarylfluorene, triarylamine, diaryl ethers, etc., are also to be regarded as aromatic ring systems for the purposes of this invention. Part of the aromatic or heteroaromatic ring system here may also be a condensed group.

For the purposes of this invention, a cyclic alkyl group is taken to mean both monocyclic and bi- and polycyclic alkyl groups.

For the purposes of the present invention, a  $C_1$ - to  $C_{40}$ -alkyl group, in which, in addition, individual H atoms or CH<sub>2</sub> groups may be substituted by the above-mentioned groups, is particularly preferably taken to mean the radicals methyl, ethyl, n-propyl, i-propyl, n-butyl, i-butyl, s-butyl, t-butyl, 40 2-methylbutyl, n-pentyl, s-pentyl, cyclopentyl, n-hexyl, cyclohexyl, n-heptyl, cycloheptyl, n-octyl, cyclooctyl, 2-ethylhexyl, trifluoromethyl, pentafluoroethyl, 2,2,2-trifluoroethyl, ethenyl, propenyl, butenyl, pentenyl, cyclopentenyl, hexenyl, cyclohexenyl, heptenyl, cycloheptenyl, octenyl, cyclooctenyl, ethynyl, propynyl, butynyl, pentynyl, hexynyl or octynyl. A C<sub>1</sub>- to C<sub>40</sub>-alkoxy group is particularly preferably taken to mean methoxy, trifluoro-methoxy, ethoxy, n-propoxy, i-propoxy, n-butoxy, i-butoxy, s-butoxy, t-butoxy or 2-methylbutoxy. An aromatic or heteroaromatic ring system having 1 to 30 aromatic ring atoms, which may in each 50 case also be substituted by the above-mentioned radicals R<sup>1</sup> and R<sup>2</sup> and which may be linked to the aromatic or heteroaromatic via any desired positions, is taken to mean, in particular, groups derived from benzene, naphthalene, anthracene, phenanthrene, pyrene, chrysene, perylene, fluoranthene, tet- 55 racene, pentacene, benzopyrene, biphenyl, biphenylene, terphenyl, terphenylene, fluorene, spirobifluorene, truxene, isotruxene, dihydrophenanthrene, dihydropyrene, tetrahydropyrene, cis- or trans-indenofluorene, furan, benzofuran, isobenzofuran, dibenzofuran, thiophene, benzothiophene, 60 isobenzothiophene, dibenzothiophene, pyrrole, indole, isoindole, carbazole, pyridine, quinoline, isoquinoline, acridine, phenanthridine, benzo-5,6-quinoline, benzo-6,7-quinoline, benzo-7,8-quinoline, phenothiazine, phenoxazine, pyrazole, indazole, imidazole, benzimidazole, naphthimidazole, 65 phenanthrimidazole, pyridimidazole, pyrazinimidazole, quinoxalinimidazole, oxazole, benzoxazole, naphthoxazole,

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anthroxazole, phenanthroxazole, isoxazole, 1,2-thiazole, 1,3-thiazole, benzothiazole, pyridazine, benzopyridazine, pyrimidine, benzopyrimidine, quinoxaline, pyrazine, phenazine, naphthyridine, azacarbazole, benzocarboline, phenanthroline, 1,2,3-triazole, 1,2,4-triazole, benzotriazole, 1,2,3-oxadiazole, 1,2,4-oxadiazole, 1,2,5-oxadiazole, 1,3,4-oxadiazole, 1,2,3-thiadiazole, 1,2,4-thiadiazole, 1,3,4-thiadiazole, 1,3,5-triazine, 1,2,4-triazine, 1,2,3-triazine, tetrazole, 1,2,4,5-tetrazine, 1,2,3,4-tetrazine, 1,2,3,5-tetrazine, purine, pteridine, indolizine, benzothiadiazole, triphenylamine, diphenylamine, diphenylamine, and tolan.

Preferred embodiments of compounds of the formula (1) are described below.

Preference is given to compounds of the formula (1) in which the symbol Ar stands for an aryl or heteroaryl group having 6 to 16 aromatic ring atoms, which may be substituted by R<sup>1</sup>. The symbol Ar particularly preferably stands for phenyl, 2-pyridyl, 3-pyridyl, 4-pyridyl, 1-naphthyl, 2-naphthyl, 2-anthryl, 9-anthryl, 2-phenanthrenyl, 3-phenanthrenyl, 9-phenanthrenyl, 1-pyrenyl or 2-pyrenyl. The symbol Ar very particularly preferably stands for phenyl, 1-naphthyl, 2-naphthyl or 9-anthryl.

Both compounds of the formula (1) in which the two substituents Ar are selected identically and also compounds of the formula (1) in which the substituents Ar are different are in accordance with the invention. In a preferred embodiment of the invention, the two symbols Ar are selected identically. Particular preference is therefore given to the compounds of the formulae (2), (3), (4) and (5)

$$\begin{bmatrix} R \end{bmatrix}_{n}$$

$$\begin{bmatrix} R \end{bmatrix}_{n}$$

$$\begin{bmatrix} R \end{bmatrix}_{n}$$

$$\begin{bmatrix} R \end{bmatrix}_{n}$$

Formula (5)

$$\begin{bmatrix} R \\ p \end{bmatrix}_{p}$$

$$\begin{bmatrix} R^{1} \\ n \end{bmatrix}_{n}$$

$$\begin{bmatrix} R^{1} \\ n \end{bmatrix}_{n}$$

$$\begin{bmatrix} R^{1} \\ n \end{bmatrix}_{n}$$

in which R, R<sup>1</sup>, n and p have the same meaning as described above, and q stands for 0, 1, 2, 3, 4 or 5

In the compounds of the formulae (1) and (2) to (5), the phenyl groups in the 9- and 10-position on the anthracene may have hindered rotation about the anthracene-phenyl bond. For the purposes of this invention, hindered rotation is taken to mean a rotation barrier of at least 80 kJ/mol preferably at least 100 kJ/mol, in particular at least 120 kJ/mol at room temperature. This rotation barrier can be determined experimentally by temperature-dependent NMR measurements. If the compound of the formulae (1) and (2) to (5) exhibits atropisomerism about one or more bonds, the corresponding isolated or enriched atropisomers are in each case also a subject-matter of the invention. This relates both to enantiomers and also to diastereomers. Hindered rotation about the anthracene-phenyl bond is achieved by sufficiently large substituents R.

Preference is furthermore given to compounds of the formulae (1) and (2) to (5) in which the symbol R stands for 65  $Si(R^2)_3$ ,  $N(Ar^1)_2$ ,  $C(=O)Ar^1$ ,  $P(=O)(Ar^1)_2$ , a straight-chain alkyl or alkoxy group having 1 to 10 C atoms or a branched or

cyclic alkyl or alkoxy group having 3 to 10 C atoms, each of which may be substituted by one or more radicals R<sup>2</sup>, where one or more non-adjacent CH2 groups may be replaced by —R<sup>2</sup>C=CR<sup>2</sup>— or —O— and where one or more H atoms may be replaced by F, or for an aryl or heteroaryl group having 5 to 16 aromatic ring atoms, which may be substituted by one or more radicals R<sup>2</sup>, or a combination of two, three or four of these systems; adjacent substituents R and R<sup>1</sup> here may also form a mono- or polycyclic, aliphatic ring system with one another. R particularly preferably stands for Si(R<sup>2</sup>)<sub>3</sub>, a straight-chain alkyl group having 1 to 4 C atoms or a branched alkyl group having 3 to 5 C atoms, each of which may be substituted by one or more radicals R<sup>2</sup>, where one or more H atoms may be replaced by F, or for an aryl or heteroaryl group having 6 to 14 aromatic ring atoms, which may be substituted by one or more radicals R<sup>2</sup>, or a combination of two or three of these systems; adjacent substituents R and R1 here may also form a mono- or polycyclic, aliphatic ring system with 20 one another.

Both compounds of the formulae (1) and (2) to (5) in which the two substituents R are selected identically and also compounds of the formulae (1) and (2) to (5) in which the two substituents R are different are in accordance with the invention. The two substituents R are preferably selected identically.

Preference is furthermore given to compounds of the formulae (1) and (2) to (5) in which the symbol R<sup>1</sup>, identically or differently on each occurrence, stands for  $Si(R^2)_3$ , F,  $N(Ar^1)_2$ , 30 a straight-chain alkyl or alkoxy group having 1 to 6 C atoms or a branched or cyclic alkyl or alkoxy group having 3 to 10 C atoms, where in each case one or more CH2 groups may be replaced by  $-R^2C$  =  $CR^2$  - or - O - and where in each case one or more H atoms may be replaced by F, or an aryl or 35 heteroaryl group having 5 to 14 aromatic ring atoms, which may be substituted by one or more radicals R<sup>2</sup>, or a combination of two or three of these systems; two or more radicals R<sup>1</sup> here may also form a mono- or polycyclic, aliphatic ring system with one another or with an adjacent radical R. Par-40 ticularly preferred radicals R<sup>1</sup> are selected from the group consisting of Si(R<sup>2</sup>)<sub>3</sub>, F, straight-chain alkyl groups having 1 to 4 C atoms or branched alkyl groups having 3 to 5 C atoms, where in each case one or more H atoms may be replaced by F, or aryl or heteroaryl groups having 6 to 10 aromatic ring 45 atoms, or a combination of two of these systems; two or more adjacent radicals R<sup>1</sup> here may also form a mono- or polycyclic, aliphatic ring system with one another or with an adjacent radical R.

If one of the radicals R and/or  $R^1$  stands for a group of the formula  $N(Ar^1)_2$ , it preferably stands for a group of the formula (6) or (7)

Formula (6)

$$\begin{bmatrix} \mathbb{R}^2 \end{bmatrix}_r$$

$$X$$

$$\begin{bmatrix} \mathbb{R}^2 \end{bmatrix}_r$$

where  $R^2$  has the above-mentioned meaning and furthermore: X stands for a single bond, O, S,  $N(R^2)$  or  $C(R^2)_2$ ;

Ar¹ is, identically or differently on each occurrence, an aryl or heteroaryl group having 5 to 20 aromatic ring atoms or a triarylamine group having 15 to 30 aromatic ring atoms, each of which may be substituted by one or more radicals R¹, preferably an aryl or heteroaryl group having 6 to 14 aromatic ring atoms or a triarylamine group having 18 to 26 aromatic ring atoms, each of which may be substituted by one or more non-aromatic radicals R¹, particularly preferably phenyl, o-tolyl, p-tolyl, o-fluorophenyl, p-fluorophenyl, 1-naphthyl, 2-naphthyl, triphenylamine or naphthyl-diphenylamine;

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r is on each occurrence, identically or differently, 0 or 1, preferably 0.

Preference is furthermore given to compounds of the formulae (1) and (2) to (5) in which the index n stands for 0 or 1, particularly preferably for 0.

Preference is furthermore given to compounds of the formulae (1) and (2) to (5) in which the index p stands for 0, 1 or 2, particularly preferably for 0 or 1.

Preference is furthermore given to compounds of the formula (2) in which the index q stands for 0, 1, 2 or 3, particularly preferably for 0, 1 or 2, very particularly preferably for 0 or 1.

Preference is furthermore given to compounds of the formula (1) whose molecular weight is between 500 and 2000 g/mol, particularly preferably between 600 and 1500 g/mol.

Examples of preferred compounds of the formula (1) are compounds (1) to (50) depicted below.

(6)

(8)

-continued (5)

(16)

(26)

-continued (24)

(28)

-continued

(32)

(33)

$$\begin{array}{c} (35) \\ (36) \\ (36) \\ (37) \\ (38) \\ (38) \\ (38) \\ (39) \\ (3$$

(38)

F———F

(42)

(44)

(50)

Table 1 below indicates further preferred structures of the formula (1). The symbols and indices used in the table relate  $_{40}$  to formula (8) depicted below:

Ar here stands for a group of the formula (9), (10) or (11):

60

-continued
Formula (10)

Formula (11)

where the dashed bond denotes the link to the anthracene unit.

Furthermore, the abbreviation  $N(p-Tol)_2$  in Table 1 stands for a bis(para-tolyl)amino group.

# 36 TABLE 1-continued

101 a 01	s(рага-юту	1)allillo g	toup.					Pre	ferred struct	tures of the forn	nula (8)	
		TA	ABLE 1					_		Ar		
	Pre	ferred structi	ares of the forn	nula (8)		5	No.	Ar	Rc	Rd	Ra	Rb
	_		Ar				71	Phenyl	Н	tert-Butyl	tert-Butyl	N(p-Tol) <sub>2</sub>
NT-	A	D -	D.J	D -	D.I.		72	Phenyl	Н	tert-Butyl	tert-Butyl	Phenyl
No.	Ar	Rc	Rd	Ra	Rb		73	Phenyl	Н	tert-Butyl	Si(Me) <sub>3</sub>	H
1	Phenyl	Н	Н	Methyl	Н	10	74 75	Phenyl Phenyl	H H	tert-Butyl tert-Butyl	Si(Me) <sub>3</sub> Si(Me) <sub>3</sub>	Methyl tert-Butyl
2	Phenyl	H	H	Methyl	Methyl		76	Phenyl	H	tert-Butyl	Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub>
3	Phenyl	Н	H	Methyl	tert-Butyl		77	Phenyl	Н	tert-Butyl	$Si(Me)_3$	$N(p-Tol)_2$
4 5	Phenyl Phenyl	H H	H H	Methyl Methyl	Si(Me) <sub>3</sub> N(p-Tol) <sub>2</sub>		78	Phenyl	Н	tert-Butyl	Si(Me) <sub>3</sub>	Phenyl
6	Phenyl	Н	Н	Methyl	Phenyl		79 <b>8</b> 0	Phenyl	H H	tert-Butyl	N(p-Tol) <sub>2</sub>	H Mathril
7	Phenyl	H	Н	tert-Butyl	Н	15	81	Phenyl Phenyl	н Н	tert-Butyl tert-Butyl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	Methyl tert-Butyl
8	Phenyl	H	H	tert-Butyl	Methyl		82	Phenyl	Н	tert-Butyl	$N(p-Tol)_2$	Si(Me) <sub>3</sub>
9	Phenyl	H	Н	tert-Butyl	tert-Butyl		83	Phenyl	Н	tert-Butyl	$N(p-Tol)_2$	$N(p-Tol)_2$
10 11	Phenyl Phenyl	H H	H H	tert-Butyl tert-Butyl	$Si(Me)_3$ $N(p-Tol)_2$		84	Phenyl	Н	tert-Butyl	N(p-Tol) <sub>2</sub>	Phenyl
12	Phenyl	Н	Н	tert-Butyl	Phenyl		85	Phenyl	H H	tert-Butyl	Phenyl	H Mathril
13	Phenyl	H	Н	$Si(Me)_3$	Н	20	86 87	Phenyl Phenyl	н Н	tert-Butyl tert-Butyl	Phenyl Phenyl	Methyl tert-Butyl
14	Phenyl	H	H	$Si(Me)_3$	Methyl		88	Phenyl	Н	tert-Butyl	Phenyl	Si(Me) <sub>3</sub>
15	Phenyl	Н	H	$Si(Me)_3$	tert-Butyl		89	Phenyl	Н	tert-Butyl	Phenyl	$N(p-Tol)_2$
16 17	Phenyl Phenyl	H H	H H	Si(Me) <sub>3</sub> Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub> N(p-Tol) <sub>2</sub>		90	Phenyl	Н	tert-Butyl	Phenyl	Phenyl
18	Phenyl	H	H	$Si(Me)_3$ $Si(Me)_3$	Phenyl		91	Phenyl	H	$Si(Me)_3$	Methyl	H
19	Phenyl	H	H	$N(p-Tol)_2$	Н	25	92 93	Phenyl Phenyl	H H	Si(Me) <sub>3</sub> Si(Me) <sub>3</sub>	Methyl Methyl	Methyl tert-Butyl
20	Phenyl	H	Н	$N(p-Tol)_2$	Methyl	20	94	Phenyl	H	$Si(Me)_3$ $Si(Me)_3$	Methyl	Si(Me) <sub>3</sub>
21	Phenyl	H	H	N(p-Tol) <sub>2</sub>	tert-Butyl		95	Phenyl	Н	Si(Me) <sub>3</sub>	Methyl	N(p-Tol) <sub>2</sub>
22 23	Phenyl Phenyl	H H	Н	N(p-Tol) <sub>2</sub>	Si(Me) <sub>3</sub>		96	Phenyl	Н	Si(Me) <sub>3</sub>	Methyl	Phenyl
23	Phenyl	п Н	H H	$N(p-Tol)_2$ $N(p-Tol)_2$	N(p-Tol) <sub>2</sub> Phenyl		97	Phenyl	Н	Si(Me) <sub>3</sub>	tert-Butyl	H
25	Phenyl	H	Н	Phenyl	Н	20	98 99	Phenyl Phenyl	H H	$Si(Me)_3$ $Si(Me)_3$	tert-Butyl tert-Butyl	Methyl tert-Butyl
26	Phenyl	H	Н	Phenyl	Methyl	30	100	Phenyl	Н	$Si(Me)_3$	tert-Butyl	Si(Me) <sub>3</sub>
27	Phenyl	H	H	Phenyl	tert-Butyl		101	Phenyl	H	Si(Me) <sub>3</sub>	tert-Butyl	$N(p-Tol)_2$
28	Phenyl	H	Н	Phenyl	Si(Me) <sub>3</sub>		102	Phenyl	Н	$Si(Me)_3$	tert-Butyl	Phenyl
29 30	Phenyl Phenyl	H H	H H	Phenyl Phenyl	N(p-Tol) <sub>2</sub> Phenyl		103	Phenyl	H	Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub>	Н
31	Phenyl	Н	Methyl	Methyl	H		104 105	Phenyl Phenyl	H H	Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub>	Methyl tert-Butyl
32	Phenyl	H	Methyl	Methyl	Methyl	35	106	Phenyl	н Н	$Si(Me)_3$ $Si(Me)_3$	Si(Me) <sub>3</sub> Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub>
33	Phenyl	H	Methyl	Methyl	tert-Butyl		107	Phenyl	H	Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub>	$N(p-Tol)_2$
34 35	Phenyl Phenyl	H H	Methyl	Methyl	Si(Me) <sub>3</sub>		108	Phenyl	Н	Si(Me) <sub>3</sub>	$Si(Me)_3$	Phenyl
35 36	Phenyl	н Н	Methyl Methyl	Methyl Methyl	N(p-Tol) <sub>2</sub> Phenyl		109	Phenyl	Н	Si(Me) <sub>3</sub>	N(p-Tol) <sub>2</sub>	H
37	Phenyl	Н	Methyl	tert-Butyl	Н		110 111	Phenyl Phenyl	H H	$Si(Me)_3$ $Si(Me)_3$	$N(p-Tol)_2$ $N(p-Tol)_2$	Methyl tert-Butyl
38	Phenyl	H	Methyl	tert-Butyl	Methyl	40	111	Phenyl	Н	$Si(Me)_3$ $Si(Me)_3$	$N(p-Tol)_2$ $N(p-Tol)_2$	Si(Me) <sub>3</sub>
39	Phenyl	H	Methyl	tert-Butyl	tert-Butyl		113	Phenyl	Н	Si(Me) <sub>3</sub>	$N(p-Tol)_2$	$N(p-Tol)_2$
40	Phenyl	H	Methyl	tert-Butyl tert-Butyl	Si(Me) <sub>3</sub>		114	Phenyl	Н	Si(Me) <sub>3</sub>	$N(p-Tol)_2$	Phenyl
41 42	Phenyl Phenyl	H H	Methyl Methyl	tert-Butyl	N(p-Tol) <sub>2</sub> Phenyl		115	Phenyl	H	$Si(Me)_3$	Phenyl	H
43	Phenyl	Н	Methyl	Si(Me) <sub>3</sub>	Н		116 117	Phenyl Phenyl	H H	Si(Me) <sub>3</sub> Si(Me) <sub>3</sub>	Phenyl Phenyl	Methyl tert-Butyl
44	Phenyl	H	Methyl	$Si(Me)_3$	Methyl	45	118	Phenyl	H	Si(Me)3	Phenyl	Si(Me) <sub>3</sub>
45	Phenyl	H	Methyl	$Si(Me)_3$	tert-Butyl		119	Phenyl	Н	Si(Me) <sub>3</sub>	Phenyl	$N(p-Tol)_2$
46	Phenyl	H	Methyl	Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub>		120	Phenyl	Н	$Si(Me)_3$	Phenyl	Phenyl
47 48	Phenyl Phenyl	H H	Methyl Methyl	$Si(Me)_3$ $Si(Me)_3$	N(p-Tol) <sub>2</sub> Phenyl		121	Phenyl	Н	N(p-Tol) <sub>2</sub>	Methyl	H
49	Phenyl	Н	Methyl	N(p-Tol) <sub>2</sub>	Н		122 123	Phenyl Phenyl	H H	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	Methyl Methyl	Methyl tert-Butyl
50	Phenyl	H	Methyl	$N(p-Tol)_2$	Methyl	50	123	Phenyl	н Н	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	Methyl	Si(Me) <sub>3</sub>
51	Phenyl	H	Methyl	$N(p-Tol)_2$	tert-Butyl	50	125	Phenyl	Н	$N(p-Tol)_2$	Methyl	$N(p-Tol)_2$
52	Phenyl	H	Methyl	N(p-Tol) <sub>2</sub>	Si(Me) <sub>3</sub>		126	Phenyl	Н	$N(p-Tol)_2$	Methyl	Phenyl
53 54	Phenyl Phenyl	H H	Methyl Methyl	$N(p-Tol)_2$ $N(p-Tol)_2$	N(p-Tol) <sub>2</sub> Phenyl		127	Phenyl	Н	N(p-Tol) <sub>2</sub>	tert-Butyl	H
55	Phenyl	Н	Methyl	Phenyl	Н		128 129	Phenyl Phenyl	Н	N(p-Tol) <sub>2</sub>	tert-Butyl tert-Butyl	Methyl tert-Butyl
56	Phenyl	H	Methyl	Phenyl	Methyl		130	Phenyl	H H	$N(p-Tol)_2$ $N(p-Tol)_2$	tert-Butyl	Si(Me) <sub>3</sub>
57	Phenyl	Η	Methyl	Phenyl	tert-Butyl	55	131	Phenyl	Н	N(p-Tol) <sub>2</sub>	tert-Butyl	N(p-Tol) <sub>2</sub>
58	Phenyl	H	Methyl	Phenyl	Si(Me) <sub>3</sub>		132	Phenyl	Н	N(p-Tol) <sub>2</sub>	tert-Butyl	Phenyl
59 60	Phenyl Phenyl	H	Methyl Methyl	Phenyl Phenyl	N(p-Tol) <sub>2</sub> Phenyl		133	Phenyl	Н	N(p-Tol) <sub>2</sub>	$Si(Me)_3$	Н
61	Phenyl	H H	tert-Butyl	Methyl	Н		134	Phenyl	Н	N(p-Tol) <sub>2</sub>	Si(Me) <sub>3</sub>	Methyl
62	Phenyl	Н	tert-Butyl	Methyl	Methyl		135 136	Phenyl Phenyl	H H	$N(p-Tol)_2$ $N(p-Tol)_2$	$Si(Me)_3$ $Si(Me)_3$	tert-Butyl Si(Me) <sub>3</sub>
63	Phenyl	H	tert-Butyl	Methyl	tert-Butyl	60	137	Phenyl	н Н	$N(p-Tol)_2$ $N(p-Tol)_2$	$Si(Me)_3$	$N(p-Tol)_2$
64	Phenyl	Н	tert-Butyl	Methyl	Si(Me)3		138	Phenyl	Н	$N(p-Tol)_2$	$Si(Me)_3$	Phenyl
65	Phenyl	H	tert-Butyl	Methyl	N(p-Tol) <sub>2</sub>		139	Phenyl	Н	$N(p-Tol)_2$	$N(p-Tol)_2$	Н
66	Phenyl	H	tert-Butyl	Methyl	Phenyl		140	Phenyl	Н	N(p-Tol) <sub>2</sub>	N(p-Tol) <sub>2</sub>	Methyl
67 68	Phenyl Phenyl	H H	tert-Butyl tert-Butyl	tert-Butyl tert-Butyl	H Methyl		141 142	Phenyl Phenyl	H H	N(p-Tol) <sub>2</sub>	N(p-Tol) <sub>2</sub>	tert-Butyl
69	Phenyl	H H	tert-Butyl	tert-Butyl	tert-Butyl	65	143	Phenyl	H H	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	$N(p-Tol)_2$ $N(p-Tol)_2$	Si(Me) <sub>3</sub> N(p-Tol) <sub>2</sub>
70	Phenyl	Н	tert-Butyl	tert-Butyl	Si(Me) <sub>3</sub>	-	144	Phenyl	H	$N(p-Tol)_2$ $N(p-Tol)_2$	$N(p-Tol)_2$ $N(p-Tol)_2$	Phenyl
			2000,1	2500,1	(/3					- (r 201)2	(r ***)2	,-

		TABLE	1-continue	d					TABLE 1	-continu	ed	
	Pr	eferred structu	res of the forn	ıula (8)				Pr	eferred structure	s of the for	rmula (8)	
			vr.	, ,					Ar			
No.	Ar	Rc	Rd	Ra	Rb	5	No.	Ar	Rc	Rd	Ra	Rb
145	Phenyl	Н	N(p-Tol) <sub>2</sub>	Phenyl	Н		219	Phenyl	Si(Me)3	Н	tert-Butyl	tert-Butyl
146	Phenyl	H	$N(p-Tol)_2$	Phenyl	Methyl		220	Phenyl	$Si(Me)_3$	H	tert-Butyl	$Si(Me)_3$
147	Phenyl	H	N(p-Tol) <sub>2</sub>	Phenyl	tert-Butyl		221	Phenyl	Si(Me) <sub>3</sub>	Н	tert-Butyl	N(p-Tol) <sub>2</sub>
148 149	Phenyl Phenyl	H H	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	Phenyl Phenyl	$Si(Me)_3$ $N(p-Tol)_2$	10	222 223	Phenyl Phenyl	Si(Me) <sub>3</sub>	H H	tert-Butyl Si(Me) <sub>3</sub>	Phenyl H
150	Phenyl	Н	$N(p-Tol)_2$ $N(p-Tol)_2$	Phenyl	Phenyl		224	Phenyl	$Si(Me)_3$ $Si(Me)_3$	Н	$Si(Me)_3$ $Si(Me)_3$	Methyl
151	Phenyl	Methyl	Н	Methyl	Н		225	Phenyl	Si(Me) <sub>3</sub>	Н	Si(Me) <sub>3</sub>	tert-Butyl
152	Phenyl	Methyl	Н	Methyl	Methyl		226	Phenyl	Si(Me) <sub>3</sub>	H	Si(Me) <sub>3</sub>	$Si(Me)_3$
153	Phenyl	Methyl	H	Methyl	tert-Butyl		227	Phenyl	$Si(Me)_3$	H	$Si(Me)_3$	N(p-Tol) <sub>2</sub>
154	Phenyl	Methyl	Н	Methyl	Si(Me) <sub>3</sub>	15	228	Phenyl	Si(Me)3	Н	Si(Me)3	Phenyl
155 156	Phenyl Phenyl	Methyl Methyl	H H	Methyl Methyl	N(p-Tol) <sub>2</sub> Phenyl		229 230	Phenyl Phenyl	$Si(Me)_3$ $Si(Me)_3$	H H	$Si(Me)_3$ $N(p-Tol)_2$	H Methyl
157	Phenyl	Methyl	H	tert-Butyl	H		231	Phenyl	$Si(Me)_3$	Н	$N(p-Tol)_2$	tert-Butyl
158	Phenyl	Methyl	Н	tert-Butyl	Methyl		232	Phenyl	Si(Me) <sub>3</sub>	Н	$N(p-Tol)_2$	$Si(Me)_3$
159	Phenyl	Methyl	Н	tert-Butyl	tert-Butyl		233	Phenyl	$Si(Me)_3$	Η	$N(p-Tol)_2$	$N(p-Tol)_2$
160	Phenyl	Methyl	H	tert-Butyl	Si(Me) <sub>3</sub>	20	234	Phenyl	Si(Me) <sub>3</sub>	H	N(p-Tol) <sub>2</sub>	Phenyl
161 162	Phenyl Phenyl	Methyl Methyl	H H	tert-Butyl tert-Butyl	N(p-Tol) <sub>2</sub> Phenyl	20	235 236	Phenyl Phenyl	$Si(Me)_3$ $Si(Me)_3$	H H	Phenyl Phenyl	H Methyl
163	Phenyl	Methyl	Н	Si(Me) <sub>3</sub>	H		237	Phenyl	$Si(Me)_3$ $Si(Me)_3$	Н	Phenyl	tert-Butyl
164	Phenyl	Methyl	Н	$Si(Me)_3$	Methyl		238	Phenyl	Si(Me) <sub>3</sub>	Н	Phenyl	Si(Me) <sub>3</sub>
165	Phenyl	Methyl	Н	$Si(Me)_3$	tert-Butyl		239	Phenyl	$Si(Me)_3$	Н	Phenyl	$N(p-Tol)_2$
166	Phenyl	Methyl	H	Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub>	2.5	240	Phenyl	Si(Me) <sub>3</sub>	H	Phenyl	Phenyl
167	Phenyl	Methyl	Н	$Si(Me)_3$	N(p-Tol) <sub>2</sub>	25	241	Phenyl	N(p-Tol) <sub>2</sub>	Н	Methyl	H
168 169	Phenyl Phenyl	Methyl Methyl	H H	$Si(Me)_3$ $N(p-Tol)_2$	Phenyl H		242 243	Phenyl Phenyl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	H H	Methyl Methyl	Methyl tert-Butyl
170	Phenyl	Methyl	Н	$N(p - Tol)_2$	Methyl		244	Phenyl	$N(p - Tol)_2$	Н	Methyl	Si(Me) <sub>3</sub>
171	Phenyl	Methyl	Н	$N(p-Tol)_2$	tert-Butyl		245	Phenyl	$N(p-Tol)_2$	Н	Methyl	N(p-Tol) <sub>2</sub>
172	Phenyl	Methyl	Н	$N(p-Tol)_2$	$Si(Me)_3$		246	Phenyl	$N(p-Tol)_2$	Н	Methyl	Phenyl
173	Phenyl	Methyl	H	N(p-Tol) <sub>2</sub>	N(p-Tol) <sub>2</sub>	30	247	Phenyl	N(p-Tol) <sub>2</sub>	Н	tert-Butyl	H
174 175	Phenyl Phenyl	Methyl Methyl	H H	N(p-Tol) <sub>2</sub> Phenyl	Phenyl H		248 249	Phenyl Phenyl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	H H	tert-Butyl tert-Butyl	Methyl tert-Butyl
176	Phenyl	Methyl	п Н	Phenyl	п Methyl		250	Phenyl	$N(p-Tol)_2$ $N(p-Tol)_2$	Н	tert-Butyl	Si(Me) <sub>3</sub>
177	Phenyl	Methyl	Н	Phenyl	tert-Butyl		251	Phenyl	$N(p-Tol)_2$	Н	tert-Butyl	N(p-Tol) <sub>2</sub>
178	Phenyl	Methyl	H	Phenyl	$Si(Me)_3$		252	Phenyl	$N(p-Tol)_2$	Н	tert-Butyl	Phenyl
179	Phenyl	Methyl	H	Phenyl	N(p-Tol) <sub>2</sub>	35	253	Phenyl	$N(p-Tol)_2$	H	$Si(Me)_3$	Н
180 181	Phenyl	Methyl	H H	Phenyl	Phenyl H		254 255	Phenyl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	H H	Si(Me) <sub>3</sub>	Methyl
182	Phenyl Phenyl	tert-Butyl tert-Butyl	п Н	Methyl Methyl	п Methyl		256	Phenyl Phenyl	$N(p-Tol)_2$ $N(p-Tol)_2$	Н	$Si(Me)_3$ $Si(Me)_3$	tert-Butyl Si(Me) <sub>3</sub>
183	Phenyl	tert-Butyl	H	Methyl	tert-Butyl		257	Phenyl	$N(p-Tol)_2$	Н	Si(Me) <sub>3</sub>	$N(p-Tol)_2$
184	Phenyl	tert-Butyl	H	Methyl	$Si(Me)_3$		258	Phenyl	$N(p-Tol)_2$	Η	Si(Me) <sub>3</sub>	Phenyl
185	Phenyl	tert-Butyl	Н	Methyl	$N(p-Tol)_2$	40	259	Phenyl	$N(p-Tol)_2$	Н	$N(p-Tol)_2$	Н
186	Phenyl	tert-Butyl	H	Methyl	Phenyl	-10	260	Phenyl	N(p-Tol) <sub>2</sub>	Н	N(p-Tol) <sub>2</sub>	Methyl tert-Butyl
187 188	Phenyl Phenyl	tert-Butyl tert-Butyl	H H	tert-Butyl tert-Butyl	H Methyl		261 262	Phenyl Phenyl	$N(p-Tol)_2$ $N(p-Tol)_2$	H H	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	Si(Me) <sub>3</sub>
189	Phenyl	tert-Butyl	H	tert-Butyl	tert-Butyl		263	Phenyl	$N(p-Tol)_2$	Н	$N(p-Tol)_2$	N(p-Tol) <sub>2</sub>
190	Phenyl	tert-Butyl	H	tert-Butyl	$Si(Me)_3$		264	Phenyl	$N(p-Tol)_2$	H	$N(p-Tol)_2$	Phenyl
191	Phenyl	tert-Butyl	Н	tert-Butyl	N(p-Tol) <sub>2</sub>	45	265	Phenyl	N(p-Tol) <sub>2</sub>	Н	Phenyl	Н
192 193	Phenyl Phenyl	tert-Butyl tert-Butyl	H H	tert-Butyl Si(Me) <sub>3</sub>	Phenyl H	45	266 267	Phenyl Phenyl	$N(p-Tol)_2$ $N(p-Tol)_2$	H H	Phenyl Phenyl	Methyl tert-Butyl
193	Phenyl	tert-Butyl	H	$Si(Me)_3$ $Si(Me)_3$	Methyl		268	Phenyl	$N(p-Tol)_2$ $N(p-Tol)_2$	Н	Phenyl	Si(Me) <sub>3</sub>
195	Phenyl	tert-Butyl	Н	$Si(Me)_3$	tert-Butyl		269	Phenyl	$N(p-Tol)_2$	Н	Phenyl	N(p-Tol) <sub>2</sub>
196	Phenyl	tert-Butyl	Η	$Si(Me)_3$	$Si(Me)_3$		270	Phenyl	$N(p-Tol)_2$	Η	Phenyl	Phenyl
197	Phenyl	tert-Butyl	Н	Si(Me)3	N(p-Tol) <sub>2</sub>		271	Phenyl	Phenyl	Н	Methyl	Н
198 199	Phenyl Phenyl	tert-Butyl tert-Butyl	H H	Si(Me) <sub>3</sub>	Phenyl H	50	272 273	Phenyl Phenyl	Phenyl Phenyl	H H	Methyl Methyl	Methyl tert-Butyl
200	Phenyl	tert-Butyl	п Н	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	п Methyl		274	Phenyl	Phenyl	Н	Methyl	Si(Me) <sub>3</sub>
201	Phenyl	tert-Butyl	Н	$N(p-Tol)_2$	tert-Butyl		275	Phenyl	Phenyl	Н	Methyl	N(p-Tol) <sub>2</sub>
202	Phenyl	tert-Butyl	Н	$N(p-Tol)_2$	Si(Me) <sub>3</sub>		276	Phenyl	Phenyl	H	Methyl	Phenyl
203	Phenyl	tert-Butyl	Н	$N(p-Tol)_2$	N(p-Tol) <sub>2</sub>		277	Phenyl	Phenyl	Н	tert-Butyl	Н
204	Phenyl	tert-Butyl	H	N(p-Tol) <sub>2</sub>	Phenyl	55	278	Phenyl	Phenyl	Н	tert-Butyl	Methyl
205 206	Phenyl Phenyl	tert-Butyl tert-Butyl	H H	Phenyl Phenyl	H Methyl		279 280	Phenyl Phenyl	Phenyl Phenyl	H H	tert-Butyl tert-Butyl	tert-Butyl Si(Me) <sub>3</sub>
207	Phenyl	tert-Butyl	Н	Phenyl	tert-Butyl		281	Phenyl	Phenyl	Н	tert-Butyl	$N(p-Tol)_2$
208	Phenyl	tert-Butyl	Н	Phenyl	Si(Me) <sub>3</sub>		282	Phenyl	Phenyl	Н	tert-Butyl	Phenyl
209	Phenyl	tert-Butyl	Н	Phenyl	$N(p-Tol)_2$		283	Phenyl	Phenyl	Н	$Si(Me)_3$	Н
210	Phenyl	tert-Butyl	Н	Phenyl	Phenyl	60	284	Phenyl	Phenyl	Н	Si(Me) <sub>3</sub>	Methyl
211 212	Phenyl Phenyl	$Si(Me)_3$ $Si(Me)_3$	H H	Methyl Methyl	H Methyl	5.5	285 286	Phenyl Phenyl	Phenyl Phenyl	H H	$Si(Me)_3$ $Si(Me)_3$	tert-Butyl Si(Me) <sub>3</sub>
212	Phenyl	$Si(Me)_3$ $Si(Me)_3$	Н	Methyl	tert-Butyl		287	Phenyl	Phenyl	Н	$Si(Me)_3$ $Si(Me)_3$	$N(p-Tol)_2$
214	Phenyl	$Si(Me)_3$	Н	Methyl	Si(Me) <sub>3</sub>		288	Phenyl	Phenyl	Н	$Si(Me)_3$	Phenyl
215	Phenyl	Si(Me) <sub>3</sub>	Н	Methyl	$N(p-Tol)_2$		289	Phenyl	Phenyl	Н	$N(p-Tol)_2$	Н
216	Phenyl	Si(Me) <sub>3</sub>	Н	Methyl	Phenyl	65	290	Phenyl	Phenyl	Н	N(p-Tol) <sub>2</sub>	Methyl
217	Phenyl	Si(Me) <sub>3</sub>	H	tert-Butyl	H Mathyd	65	291	Phenyl	Phenyl	Н	N(p-Tol) <sub>2</sub>	tert-Butyl
218	Phenyl	$Si(Me)_3$	Н	tert-Butyl	Methyl		292	Phenyl	Phenyl	Н	N(p-Tol) <sub>2</sub>	Si(Me) <sub>3</sub>

		IABLE	l-continue	d .					TABLE I	-continu	ea	
	Pref	erred structur	es of the form	nula (8)				Pre	ferred structure	es of the for	mula (8)	
	_	Aı	r			5			Ar		_	
No.	Ar	Rc	Rd	Ra	Rb	3	No.	Ar	Rc	Rd	Ra	Rb
293	Phenyl	Phenyl	Н	N(p-Tol) <sub>2</sub>	N(p-Tol) <sub>2</sub>		367	2-Naphthyl	_		tert-Butyl	Н
294	Phenyl	Phenyl	Н	N(p-Tol) <sub>2</sub>	Phenyl		368	2-Naphthyl	_	_	tert-Butyl	Methyl
295 296	Phenyl Phenyl	Phenyl Phenyl	H H	Phenyl Phenyl	H Methyl	10	369 370	2-Naphthyl 2-Naphthyl	_	_	tert-Butyl tert-Butyl	tert-Butyl Si(Me) <sub>3</sub>
297	Phenyl	Phenyl	H	Phenyl	tert-Butyl	10	371	2-Naphthyl	_	_	tert-Butyl	$N(p-Tol)_2$
298	Phenyl	Phenyl	Η	Phenyl	Si(Me) <sub>3</sub>		372	2-Naphthyl	_	_	tert-Butyl	Phenyl
299	Phenyl	Phenyl	H	Phenyl	N(p-Tol) <sub>2</sub>		373	2-Naphthyl	_	_	Si(Me) <sub>3</sub>	H
300 301	Phenyl 1-Naphthyl	Phenyl H	H —	Phenyl Methyl	Phenyl H		374 375	2-Naphthyl 2-Naphthyl	_	_	$Si(Me)_3$ $Si(Me)_3$	Methyl tert-Butyl
302	1-Naphthyl	H	_	Methyl	Methyl	1.5	376	2-Naphthyl	_	_	$Si(Me)_3$ $Si(Me)_3$	Si(Me) <sub>3</sub>
303	1-Naphthyl	H	_	Methyl	tert-Butyl	15	377	2-Naphthyl	_	_	$Si(Me)_3$	$N(p-Tol)_2$
304	1-Naphthyl	H	_	Methyl	Si(Me) <sub>3</sub>		378	2-Naphthyl	_	_	Si(Me) <sub>3</sub>	Phenyl
305 306	1-Naphthyl 1-Naphthyl	H H	_	Methyl Methyl	N(p-Tol) <sub>2</sub> Phenyl		379 380	2-Naphthyl 2-Naphthyl	_	_	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	H Methyl
307	1-Naphthyl	H		tert-Butyl	H		381	2-Naphthyl			$N(p-Tol)_2$ $N(p-Tol)_2$	tert-Butyl
308	1-Naphthyl	H	_	tert-Butyl	Methyl	20	382	2-Naphthyl	_	_	$N(p-Tol)_2$	Si(Me) <sub>3</sub>
309	1-Naphthyl	H	_	tert-Butyl	tert-Butyl	20	383	2-Naphthyl	_	_	$N(p-Tol)_2$	N(p-Tol) <sub>2</sub>
310 311	1-Naphthyl 1-Naphthyl	H H	_	tert-Butyl tert-Butyl	Si(Me) <sub>3</sub> N(p-Tol) <sub>2</sub>		384 385	2-Naphthyl 2-Naphthyl	_	_	N(p-Tol) <sub>2</sub> Phenyl	Phenyl H
312	1-Naphthyl	H	_	tert-Butyl	Phenyl		386	2-Naphthyl	_	_	Phenyl	Methyl
313	1-Naphthyl	H	_	$Si(Me)_3$	Н		387	2-Naphthyl	_	_	Phenyl	tert-Butyl
314	1-Naphthyl	H	_	$Si(Me)_3$	Methyl	2.5	388	2-Naphthyl	_	_	Phenyl	Si(Me) <sub>3</sub>
315 316	1-Naphthyl 1-Naphthyl	H H	_	Si(Me) <sub>3</sub>	tert-Butyl Si(Me) <sub>3</sub>	25	389 390	2-Naphthyl 2-Naphthyl	_	_	Phenyl Phenyl	N(p-Tol) <sub>2</sub> Phenyl
317	1-Naphthyl	Н	_	$Si(Me)_3$ $Si(Me)_3$	N(p-Tol)2		391	9-Anthryl	1-Naphthyl		Methyl	Н
318	1-Naphthyl	H	_	$Si(Me)_3$	N(p-Tol) <sub>2</sub>		392	9-Anthryl	1-Naphthyl	_ _ _	Methyl	Methyl
319	1-Naphthyl	H	_	N(p-Tol) <sub>2</sub>	Н		393	9-Anthryl	1-Naphthyl	_	Methyl	tert-Butyl
320 321	1-Naphthyl 1-Naphthyl	H H	_	$N(p-Tol)_2$ $N(p-Tol)_2$	Methyl tert-Butyl	30	394 395	9-Anthryl 9-Anthryl	1-Naphthyl 1-Naphthyl	_	Methyl Methyl	Si(Me) <sub>3</sub> N(p-Tol) <sub>2</sub>
322	1-Naphthyl	Н		$N(p-Tol)_2$ $N(p-Tol)_2$	Si(Me) <sub>3</sub>	30	396	9-Anthryl	1-Naphthyl	_	Methyl	Phenyl
323	1-Naphthyl	H	_	$N(p-Tol)_2$	N(p-Tol) <sub>2</sub>		397	9-Anthryl	1-Naphthyl	_	tert-Butyl	Н
324	1-Naphthyl	H	_	N(p-Tol) <sub>2</sub>	Phenyl		398	9-Anthryl	1-Naphthyl	_	tert-Butyl	Methyl
325 326	1-Naphthyl 1-Naphthyl	H H	_	Phenyl	H Methyl		399 400	9-Anthryl 9-Anthryl	1-Naphthyl 1-Naphthyl		tert-Butyl	tert-Butyl Si(Me) <sub>3</sub>
327	1-Naphthyl	н Н	_	Phenyl Phenyl	tert-Butyl	35	401	9-Anthryl	1-Naphthyl	_	tert-Butyl tert-Butyl	$N(p-Tol)_2$
328	1-Naphthyl	H	_	Phenyl	$Si(Me)_3$	33	402	9-Anthryl	1-Naphthyl	_	tert-Butyl	Phenyl
329	1-Naphthyl	Н	_	Phenyl	N(p-Tol) <sub>2</sub>		403	9-Anthryl	1-Naphthyl	_	Si(Me) <sub>3</sub>	Н
330 331	1-Naphthyl 1-Naphthyl	H Methyl	_	Phenyl Methyl	Phenyl H		404 405	9-Anthryl 9-Anthryl	1-Naphthyl 1-Naphthyl	_	$Si(Me)_3$ $Si(Me)_3$	Methyl tert-Butyl
332	1-Naphthyl	Methyl	_	Methyl	Methyl		406	9-Anthryl	1-Naphthyl	_	$Si(Me)_3$	Si(Me) <sub>3</sub>
333	1-Naphthyl	Methyl	_	Methyl	tert-Butyl	40	407	9-Anthryl	1-Naphthyl	_	Si(Me) <sub>3</sub>	$N(p-Tol)_2$
334	1-Naphthyl	Methyl	_	Methyl	Si(Me) <sub>3</sub>	40	408	9-Anthryl	1-Naphthyl	_	Si(Me) <sub>3</sub>	Phenyl
335 336	1-Naphthyl 1-Naphthyl	Methyl Methyl	_	Methyl Methyl	N(p-Tol) <sub>2</sub> Phenyl		409 410	9-Anthryl 9-Anthryl	1-Naphthyl 1-Naphthyl	_	$N(p-Tol)_2$ $N(p-Tol)_2$	H Methyl
337	1-Naphthyl	Methyl	_	tert-Butyl	Н		411	9-Anthryl	1-Naphthyl	_	$N(p - Tol)_2$	tert-Butyl
338	1-Naphthyl	Methyl	_	tert-Butyl	Methyl		412	9-Anthryl	1-Naphthyl	_	$N(p-Tol)_2$	$Si(Me)_3$
339	1-Naphthyl	Methyl	_	tert-Butyl	tert-Butyl	15	413	9-Anthryl	1-Naphthyl	_	N(p-Tol) <sub>2</sub>	N(p-Tol) <sub>2</sub>
340 341	1-Naphthyl 1-Naphthyl	Methyl Methyl	_	tert-Butyl tert-Butyl	$Si(Me)_3$ $N(p-Tol)_2$	45	414 415	9-Anthryl 9-Anthryl	1-Naphthyl 1-Naphthyl	_	N(p-Tol) <sub>2</sub> Phenyl	Phenyl H
342	1-Naphthyl	Methyl	_	tert-Butyl	Phenyl		416	9-Anthryl	1-Naphthyl	_	Phenyl	Methyl
343	1-Naphthyl	Methyl	_	$Si(Me)_3$	Н		417	9-Anthryl	1-Naphthyl	_	Phenyl	tert-Butyl
344	1-Naphthyl	Methyl	_	Si(Me) <sub>3</sub>	Methyl		418	9-Anthryl	1-Naphthyl	_	Phenyl	$Si(Me)_3$
345 346	1-Naphthyl 1-Naphthyl	Methyl Methyl	_	Si(Me) <sub>3</sub> Si(Me) <sub>3</sub>	tert-Butyl Si(Me) <sub>3</sub>	50	419 420	9-Anthryl 9-Anthryl	1-Naphthyl 1-Naphthyl	_	Phenyl Phenyl	N(p-Tol) <sub>2</sub> Phenyl
347	1-Naphthyl	Methyl	_	$Si(Me)_3$	$N(p-Tol)_2$	30	421	9-Anthryl	2-Naphthyl	_	Methyl	Н
348	1-Naphthyl	Methyl	_	$Si(Me)_3$	Phenyl		422	9-Anthryl	2-Naphthyl	_	Methyl	Methyl
349	1-Naphthyl	Methyl	_	N(p-Tol) <sub>2</sub>	H		423	9-Anthryl	2-Naphthyl	_	Methyl	tert-Butyl
350 351	1-Naphthyl 1-Naphthyl	Methyl Methyl	_	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	Methyl tert-Butyl		424 425	9-Anthryl 9-Anthryl	2-Naphthyl 2-Naphthyl	_	Methyl Methyl	$Si(Me)_3$ $N(p-Tol)_2$
352	1-Naphthyl	Methyl	_	$N(p-Tol)_2$	Si(Me) <sub>3</sub>	55	426	9-Anthryl	2-Naphthyl	_	Methyl	Phenyl
353	1-Naphthyl	Methyl	_	$N(p-Tol)_2$	$N(p-Tol)_2$	33	427	9-Anthryl	2-Naphthyl	_	tert-Butyl	Н
354	1-Naphthyl	Methyl	_	N(p-Tol) <sub>2</sub>	Phenyl		428	9-Anthryl	2-Naphthyl	_	tert-Butyl	Methyl
355 356	1-Naphthyl 1-Naphthyl	Methyl Methyl	_	Phenyl Phenyl	H Methyl		429 430	9-Anthryl 9-Anthryl	2-Naphthyl 2-Naphthyl	_	tert-Butyl tert-Butyl	tert-Butyl Si(Me) <sub>3</sub>
357	1-Naphthyl	Methyl	_	Phenyl	tert-Butyl		431	9-Anthryl	2-Naphthyl	_	tert-Butyl	$N(p-Tol)_2$
358	1-Naphthyl	Methyl	_	Phenyl	$Si(Me)_3$	60	432	9-Anthryl	2-Naphthyl	_	tert-Butyl	Phenyl
359	1-Naphthyl	Methyl	_	Phenyl	N(p-Tol) <sub>2</sub>	00	433	9-Anthryl	2-Naphthyl	_	Si(Me) <sub>3</sub>	H Mathyd
360 361	1-Naphthyl 2-Naphthyl	Methyl —	_	Phenyl Methyl	Phenyl H		434 435	9-Anthryl 9-Anthryl	2-Naphthyl 2-Naphthyl	_	$Si(Me)_3$ $Si(Me)_3$	Methyl tert-Butyl
362	2-Naphthyl	_	_	Methyl	Methyl		436	9-Anthryl	2-Naphthyl	_	Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub>
363	2-Naphthyl	_	_	Methyl	tert-Butyl		437	9-Anthryl	2-Naphthyl	_	$Si(Me)_3$	N(p-Tol) <sub>2</sub>
364 365	2-Naphthyl	_	_	Methyl	Si(Me) <sub>3</sub>	65	438	9-Anthryl	2-Naphthyl	_	Si(Me) <sub>3</sub>	Phenyl
365 366	2-Naphthyl 2-Naphthyl	_	_	Methyl Methyl	N(p-Tol) <sub>2</sub> Phenyl	03	439 440	9-Anthryl 9-Anthryl	2-Naphthyl 2-Naphthyl	_	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	H Methyl
200	2 1 mpnunyi			moniyi	1 11011y1		170	> 1 mm y1	~ 1.mpmmy1		11(P 101/2	1110111111

	Pre	eferred structure	s of the fo	rmula (8)		
		Ar		_		5
No.	Ar	Rc	Rd	Ra	Rb	
441	9-Anthryl	2-Naphthyl	_	N(p-Tol) <sub>2</sub>	tert-Butyl	
442 443	9-Anthryl 9-Anthryl	2-Naphthyl 2-Naphthyl		$N(p-Tol)_2$ $N(p-Tol)_2$	Si(Me) <sub>3</sub> N(p-Tol) <sub>2</sub>	
444	9-Anthryl	2-Naphthyl	_	$N(p-Tol)_2$	Phenyl	10
445	9-Anthryl	2-Naphthyl	_	Phenyl	Н	
446 447	9-Anthryl 9-Anthryl	2-Naphthyl 2-Naphthyl	_	Phenyl Phenyl	Methyl tert-Butyl	
448	9-Anthryl	2-Naphthyl		Phenyl	Si(Me) <sub>3</sub>	
449	9-Anthryl	2-Naphthyl	_	Phenyl	N(p-Tol) <sub>2</sub>	
450	9-Anthryl	2-Naphthyl	_	Phenyl	Phenyl	15
451 452	9-Anthryl 9-Anthryl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	_	Methyl Methyl	H Methyl	
453	9-Anthryl	$N(p-Tol)_2$	_	Methyl	tert-Butyl	
454	9-Anthryl	N(p-Tol) <sub>2</sub>	_	Methyl	Si(Me) <sub>3</sub>	
455 456	9-Anthryl 9-Anthryl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	_	Methyl Methyl	N(p-Tol) <sub>2</sub> Phenyl	
457	9-Anthryl	$N(p-Tol)_2$ $N(p-Tol)_2$		tert-Butyl	Н	20
458	9-Anthryl	$N(p-Tol)_2$	_	tert-Butyl	Methyl	
459	9-Anthryl	N(p-Tol) <sub>2</sub>	_	tert-Butyl	tert-Butyl	
460 461	9-Anthryl 9-Anthryl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	_	tert-Butyl tert-Butyl	$Si(Me)_3$ $N(p-Tol)_2$	
462	9-Anthryl	N(p-Tol) <sub>2</sub>	_	tert-Butyl	Phenyl	
463	9-Anthryl	$N(p-Tol)_2$	_	$Si(Me)_3$	Н	25
464 465	9-Anthryl 9-Anthryl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	_	Si(Me) <sub>3</sub>	Methyl	
466	9-Anthryl	$N(p-Tol)_2$ $N(p-Tol)_2$	_	$Si(Me)_3$ $Si(Me)_3$	tert-Butyl Si(Me) <sub>3</sub>	
467	9-Anthryl	$N(p-Tol)_2$	_	$Si(Me)_3$	N(p-Tol) <sub>2</sub>	
468	9-Anthryl	N(p-Tol) <sub>2</sub>	_	Si(Me) <sub>3</sub>	Phenyl	
469 470	9-Anthryl 9-Anthryl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	_	$N(p-Tol)_2$ $N(p-Tol)_2$	H Methyl	30
471	9-Anthryl	$N(p-Tol)_2$ $N(p-Tol)_2$		$N(p-Tol)_2$ $N(p-Tol)_2$	tert-Butyl	
472	9-Anthryl	$N(p-Tol)_2$	_	$N(p-Tol)_2$	Si(Me) <sub>3</sub>	
473	9-Anthryl	N(p-Tol) <sub>2</sub>	_	N(p-Tol) <sub>2</sub>	N(p-Tol) <sub>2</sub>	
474 475	9-Anthryl 9-Anthryl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	_	N(p-Tol) <sub>2</sub> Phenyl	Phenyl H	2.5
476	9-Anthryl	$N(p-Tol)_2^2$	_	Phenyl	Methyl	35
477	9-Anthryl	N(p-Tol) <sub>2</sub>	_	Phenyl	tert-Butyl	
478 479	9-Anthryl 9-Anthryl	N(p-Tol) <sub>2</sub> N(p-Tol) <sub>2</sub>	_	Phenyl Phenyl	$Si(Me)_3$ $N(p-Tol)_2$	
480	9-Anthryl	$N(p-Tol)_2$	_	Phenyl	Phenyl	
481	9-Anthryl	Phenyl	_	Methyl	Н	40
482 483	9-Anthryl 9-Anthryl	Phenyl Phenyl	_	Methyl Methyl	Methyl tert-Butyl	70
484	9-Anthryl	Phenyl	_	Methyl	Si(Me) <sub>3</sub>	
485	9-Anthryl	Phenyl	_	Methyl	N(p-Tol) <sub>2</sub>	
486	9-Anthryl	Phenyl	_	Methyl	Phenyl	
487 488	9-Anthryl 9-Anthryl	Phenyl Phenyl	_	tert-Butyl tert-Butyl	H Methyl	45
489	9-Anthryl	Phenyl	_	tert-Butyl	tert-Butyl	
490	9-Anthryl	Phenyl	_	tert-Butyl	$Si(Me)_3$	
491 492	9-Anthryl	Phenyl	_	tert-Butyl	N(p-Tol) <sub>2</sub>	
492	9-Anthryl 9-Anthryl	Phenyl Phenyl		tert-Butyl Si(Me) <sub>3</sub>	Phenyl H	
494	9-Anthryl	Phenyl	_	$Si(Me)_3$	Methyl	50
495	9-Anthryl	Phenyl	_	Si(Me) <sub>3</sub>	tert-Butyl	
496 497	9-Anthryl 9-Anthryl	Phenyl Phenyl	_	Si(Me) <sub>3</sub> Si(Me) <sub>3</sub>	Si(Me) <sub>3</sub> N(p-Tol) <sub>2</sub>	
498	9-Anthryl	Phenyl	_	$Si(Me)_3$ $Si(Me)_3$	Phenyl	
499	9-Anthryl	Phenyl	_	$N(p-Tol)_2$	Н	
500	9-Anthryl	Phenyl	_	N(p-Tol) <sub>2</sub>	Methyl	55
501 502	9-Anthryl 9-Anthryl	Phenyl Phenyl	_	$N(p-Tol)_2$ $N(p-Tol)_2$	tert-Butyl Si(Me) <sub>3</sub>	
503	9-Anthryl	Phenyl	_	$N(p-Tol)_2$ $N(p-Tol)_2$	$N(p-Tol)_2$	
504	9-Anthryl	Phenyl	_	$N(p-Tol)_2$	Phenyl	
505	9-Anthryl	Phenyl	_	Phenyl	H Mathyl	
506 507	9-Anthryl 9-Anthryl	Phenyl Phenyl	_	Phenyl Phenyl	Methyl tert-Butyl	60
508	9-Anthryl	Phenyl	_	Phenyl	Si(Me) <sub>3</sub>	
509	9-Anthryl	Phenyl	_	Phenyl	N(p-Tol) <sub>2</sub>	
510	9-Anthryl	Phenyl	_	Phenyl	Phenyl	

The compounds can be synthesised, for example, starting 65 from 2,6-dichloro- or dibromoanthraquinone. This is reacted with arylboronic acids in a Suzuki coupling to give the cor-

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responding 2,6-diarylanthraquinone. This can be reacted with an aromatic Grignard reagent in a further step and then with a reducing agent, for example tin(II) chloride, to give 2,6,9,10-tetraarylanthracene.

The present invention therefore furthermore relates to a process for the preparation of compounds of the formula (1) by reaction of 2,6-dihaloanthraquinone or an analogous sulfonic acid derivative with a boronic acid derivative of the group Ar with palladium catalysis, followed by reaction with a corresponding ortho-substituted organometallic phenyl derivative and reduction.

The process thus takes place in accordance with the following scheme:

20
O
Ar
B(OR<sup>2</sup>)<sub>2</sub>
"Pd"

25

Ar
1.

R
$$R^{\dagger}$$
2. Reduction

40

Ar

45

 $R^{\dagger}$ 
 $R^{\dagger}$ 
 $R^{\dagger}$ 
 $R^{\dagger}$ 
 $R^{\dagger}$ 

Ar, R, R<sup>1</sup>, R<sup>2</sup> and p here have the same meanings as described above. Y stands for chlorine, bromine or iodine, preferably bromine, or for a group of the formula OSO<sub>2</sub>R<sup>2</sup>. M stands for an electropositive metal, in particular lithium, magnesium or zinc, and, in the case of a divalent metal, also contains a further organic group or a group Y. The way in which a Suzuki coupling (first reaction step) is carried out and which palladium catalysts are particularly suitable for this purpose is known to the person skilled in the art of organic synthesis. The reducing agent employed in the second reaction step is preferably tin(II) chloride.

The compounds of the formula (1) can be employed in organic electroluminescent devices. They are particularly suitable for use as host material for fluorescent emitters, but

may each of which may, depending on the substitution pattern, also be employed as emitter, as hole-transport material, as hole-blocking material and/or as electron-transport material

The invention therefore furthermore relates to the use of 5 compounds of the formula (1) in organic electronic devices, in particular in organic electroluminescent devices, in particular as host material, as emitter, as hole-transport material, as hole-blocking material and/or as electron-transport material

The invention furthermore relates to organic electronic devices, in particular organic electroluminescent devices, comprising anode, cathode and at least one emitting layer, where at least one layer comprises at least one compound of the formula (1). The layer which comprises the compound of the formula (1) is preferably an emitting layer, a hole-transport layer, a hole-injection layer, a hole-blocking layer or an electron-transport layer.

Apart from the cathode, anode and emitting layer (or emitting layers), the organic electroluminescent device may also 20 comprise further layers. These may be, for example: holeinjection layer, hole-transport layer, hole-blocking layer, electron-transport layer, electron-injection layer and/or a charge-generation layer (T. Matsumoto et al., Multiphoton Organic EL Device Having Charge Generation Layer, IDMC 25 2003, Taiwan; Session 21 OLED (5)). The materials in these layers may also be doped. Each of these layers does not necessarily have to be present. Suitable hole-transport materials are, for example, aromatic amines, as usually used in accordance with the prior art and which may also be p-doped. 30 Suitable electron-transport materials are, for example, metal chelate complexes, for example AlQ<sub>3</sub>, compounds based on electron-deficient heterocycles, for example triazine derivatives, or compounds containing aromatic carbonyls or phosphine oxides, as described, for example, in WO 05/084081 35 and WO 05/084082, which may in each case also be n-doped. Suitable electron-injection materials are, in particular, fluorides and oxides of the alkali and alkaline earth metals, for example NaF, BaF<sub>2</sub>, CaF<sub>2</sub>, LiF or Li<sub>2</sub>O.

In a preferred embodiment of the invention, the compound 40 of the formula (1) is employed as host material, in particular for fluorescent emitters, and/or as electron-transport material and/or as hole-blocking material. This is the case, in particular, if the compound does not contain any substituents of the formula  $N(Ar^1)_2$ .

A host material is taken to mean the component in a system comprising host and dopant (binary mixture) which is present in the system in the higher proportion. In a system comprising a host and a plurality of dopants (ternary and higher mixtures), the host is taken to mean the component whose proportion is the highest in the mixture.

The proportion of the host material of the formula (1) in the emitting layer is between 50.0 and 99.9% by weight, preferably between 80.0 and 99.5% by weight, particularly preferably between 90.0 and 99.0% by weight. Correspondingly, 55 the proportion of the dopant in the emitting layer is between 0.1 and 50.0% by weight, preferably between 0.5 and 20.0% by weight, particularly preferably between 1.0 and 10.0% by weight.

Preferred dopants are selected from the class of the aromatic anthracenamines, the aromatic anthracenediamines, the aromatic pyrenediamines, the monostyrylamines, the distyrylamines, the tristyrylamines, the tetrastyrylamines, the styrylphosphines, the styryl ethers and the arylamines. An aromatic anthracenamine is taken to 65 mean a compound in which a diarylamino group is bonded directly to an anthracene group, preferably in the 9-position.

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An aromatic anthracenediamine is taken to mean a compound in which two diarylamino groups are bonded directly to an anthracene group, preferably in the 9,10-position. Aromatic pyrenamines and pyrenediamines are defined analogously, with the diarylamino groups preferably being bonded to the pyrene in the 1-position or in the 1,6-position. A monostyrylamine is taken to mean a compound which contains a substituted or unsubstituted styryl group and at least one, preferably aromatic, amine. A distyrylamine is taken to mean a compound which contains two substituted or unsubstituted styryl groups and at least one, preferably aromatic, amine. A tristyrylamine is taken to mean a compound which contains three substituted or unsubstituted styryl groups and at least one, preferably aromatic, amine. A tetrastyrylamine is taken to mean a compound which contains four substituted or unsubstituted styryl groups and at least one, preferably aromatic, amine. Corresponding phosphines and ethers are defined analogously to the amines. For the purposes of this invention, an arylamine or an aromatic amine is taken to mean a compound which contains three substituted or unsubstituted aromatic or heteroaromatic ring systems bonded directly to the nitrogen. At least one aryl group here is preferably a condensed aryl group having at least three rings. The styryl groups are particularly preferably stilbenes, which may also be further substituted. Particularly preferred dopants are selected from the classes of the tristilbenamines, the aromatic stilbenediamines, the anthracenediamines and the pyrenediamines, Very particularly preferred dopants are selected from the class of the tristyrylamines. Examples of dopants of this type are substituted or unsubstituted tristilbenamines or the dopants described in WO 06/000388, WO 06/058737 and WO 06/000389.

In a further embodiment of the invention, the organic electroluminescent device comprises a plurality of emitting layers, where at least one of these layers comprises at least one compound of the formula (1). These emission layers particularly preferably have in total a plurality of emission maxima between 380 nm and 750 nm, resulting overall in white emission, i.e. at least one further emitting compound which is able to fluoresce or phosphoresce and emits yellow, orange or red light is used in the further emitting layer(s). Preference is given to three-layer systems, where at least one of these layers comprises at least one compound of the formula (1) and where the three layers exhibit blue, green and orange or red 45 emission (for the basic structure, see, for example, WO 05/011013). Emitters which have broad-band emission bands and thus exhibit white emission are likewise suitable for white emission.

In addition to the compounds of the formula (1) and the dopant(s), further substances, for example hole- or electron-transport materials, may also be present in the emitting layer.

If the symbol R stands for an  $N(Ar^1)_2$  group and/or at least one substituent  $R^1$  on the Ar group or in another position stands for an  $N(Ar^1)_2$  group, the compound of the formula (1) is particularly suitable as emitting compound and/or as hole-transport material, as described in more detail below.

If the compound of the formula (1) is employed as hole-transport material, it is preferably employed in a hole-transport layer and/or in a hole-injection layer. For the purposes of this invention, a hole-injection layer is a layer which is directly adjacent to the anode. For the purposes of this invention, a hole-transport layer is a layer which is located between a hole-injection layer and an emission layer. If the compounds of the formula (1) are used as hole-transport or hole-injection material, it may be preferred for them to be doped with electron-acceptor compounds, for example with F<sub>4</sub>-TCNQ or with compounds as described in EP 1476881 or EP 1596445.

If the compound of the formula (1) is employed as emitting compound, it is preferably employed in combination with a host material.

The proportion of the emitting compound of the formula (1) in the mixture of the emitting layer is between 0.1 and 50.0% by weight, preferably between 0.5 and 20.0% by weight, particularly preferably between 1.0 and 10.0% by weight. Correspondingly, the proportion of the host material in the layer is between 50.0 and 99.9% by weight, preferably between 80.0 and 99.5% by weight, particularly preferably between 90.0 and 99.0% by weight.

Suitable host materials are various classes of substance. Preferred host materials are selected from the classes of the oligoarylenes (for example 2, 2',7,7'-tetraphenylspirobifluorene as described in EP 676461 or dinaphthylanthracene), in particular the oligoarylenes containing condensed aromatic groups, the oligoarylenevinylenes (for example DPVBi or spiro-DPVBi as described in EP 676461), the polypodal metal complexes (for example as described in WO 20 04/081017), the hole-conducting compounds (for example as described in WO 04/058911), the electron-conducting compounds, in particular ketones, phosphine oxides, sulfoxides, etc. (for example as described in WO 05/084081 or WO 05/084082), the atropisomers (for example as described in 25 WO 06/048268) or the boronic acid derivatives (for example as described in WO 06/117052). Particularly preferred host materials are selected from the classes of the oligoarylenes containing naphthalene, anthracene and/or pyrene or atropisomers of these compounds, the oligoarylenevinylenes, the 30 ketones, the phosphine oxides and the sulfoxides. Very particularly preferred host materials are selected from the classes of the oligoarylenes containing anthracene and/or pyrene or atropisomers of these compounds, the phosphine oxides and the sulfoxides.

Preference is furthermore given to an organic electroluminescent device, characterised in that one or more layers are coated by means of a sublimation process, in which the materials are vapour-deposited in vacuum sublimation units at a pressure of less than  $10^{-5}$  mbar, preferably less than  $10^{-6}$  40 mbar, particularly preferably less than  $10^{-7}$  mbar.

Preference is likewise given to an organic electroluminescent device, characterised in that one or more layers are coated by the OVPD (organic vapour phase deposition) process or with the aid of carrier-gas sublimation, in which the 45 materials are applied at a pressure between  $10^{-5}$  mbar and 1 bar.

Preference is furthermore given to an organic electroluminescent device, characterised in that one or more layers are produced from solution, such as, for example, by spin coating, or by means of any desired printing process, such as, for example, screen printing, flexographic printing or offset printing, but particularly preferably LTTI (light-induced thermal imaging, thermal transfer printing) or ink-jet printing. Soluble compounds of the formula (1) are necessary for this purpose. The compounds according to the invention are therefore very highly suitable for processing from solution since, due to the substitution, they have high solubility in organic solvents.

The organic electroluminescent devices according to the 60 invention have the following surprising properties:

- The compounds according to the invention have high thermal stability and in particular a high glass-transition temperature.
- The compounds according to the invention exhibit high 65 efficiency, a good lifetime and good colour coordinates on use in OLEDs.

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- 3. The compounds according to the invention have good solubility in organic solvents, which simplifies the preparation and processing of these compounds.
- 4. The compounds according to the invention have high redox stability (high stability to holes and electrons).
- 5. The film-formation properties of the compounds according to the invention are very good.

The present application text is directed to the use of compounds according to the invention in relation to OLEDs and the corresponding displays.

In spite of this restriction of the description, it is possible for the person skilled in the art, without further inventive step, also to use the compounds according to the invention for further uses in other electronic devices, for example for organic field-effect transistors (O-FETs), organic thin-film transistors (O-TFTs), organic light-emitting transistors (O-LETs), organic integrated circuits (O-ICs), organic solar cells (O-SCs), organic field-quench devices (O-FQDs), organic photo receptors, light-emitting electrochemical cells (LECs) or also organic laser diodes (O-lasers), to mention but a few applications.

The present invention furthermore relates to the use of the compounds according to the invention in the corresponding devices and to these devices themselves.

The invention is explained in greater detail by the following examples, without wishing to restrict it thereby.

#### **EXAMPLES**

The following syntheses are carried out under a protective-gas atmosphere, unless indicated otherwise. The starting materials can be purchased from ALDRICH or ABCR (palladium(II) acetate, tri-o-tolyl-phosphine, di-tert-butylchlorophosphine, bromides, amines, inorganics, solvents). 2,6-Dibromoanthraquinone is prepared by the method of Lee et al., *Org. Lett.* 2005, 7(2), 323; 2-trimethylsilylbromobenzene is prepared by the method of Klusener et al., *Org. Chem.* 1990, 55(4), 1311; pinacolyl 10-(4-methylnaphth-1-yl)anthracene9-boronate is prepared in accordance with EP 05009643.7; 1-bromo-2-(1-methyl-1-phenylethyl)benzene is prepared by the method of Sigmundova et al., *Synth. Commun.* 2004, 34(20), 3667.

#### Example 1

2,6,9,10-Tetra-o-tolylanthracene

a) 2,6-Bis-o-tolylanthraquinone

A suspension of 28.7 g (100 mmol) of 2,6-dibromoan-thraquinone, 32.6 g (240 mmol) of o-tolylboronic acid, 89.2 g (420 mmol) of potassium phosphate, 1.8 g (8 mmol) of triotolylphosphine and 225 mg (1 mmol) of palladium(II) acetate in a mixture of 200 ml of dioxane, 400 ml of toluene and 500 ml of water is refluxed for 16 h. After cooling, the solid is

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filtered off with suction, washed three times with 100 ml of water each time and three times with 100 ml of ethanol each time, dried in vacuo and subsequently recrystallised twice from DMF. Yield: 33.0 g (85 mmol), 84.9% of theory, purity: 98% according to NMR.

#### b) 2,6,9,1-Tetra-o-tolylanthracene

The corresponding Grignard reagent is prepared from 3.7 g 25 (153 mmol) of magnesium and 18.0 ml (150 mmol) of 2-bromotoluene in 500 ml of THF. 19.4 g (50 mmol) of 2,6-bis-otolylanthraquinone are added to the Grignard reagent. The reaction mixture is subsequently refluxed for 16 h. After cooling, 30 ml of ethanol are added, the solvent is removed in 30 vacuo, the residue is taken up in 300 ml of DMF and warmed to 60° C., and 8.9 g (65 mmol) of tin(II) chloride are then added in portions with vigorous stirring (note: exothermic reaction!). The mixture is subsequently stirred at 60° C. for a further 2 h. After cooling, 500 ml of 2.5N hydrochloric acid  $_{35}$ are added, and the solid is filtered off with suction. The solid is washed three times with 100 ml of 2.5N hydrochloric acid each time, three times with 100 ml of water each time and three times with 100 ml of ethanol each time, dried in vacuo and subsequently recrystallised three times from acetic acid 40 and twice from DMF. Sublimation p=1×10<sup>-5</sup> mbar, T=335° C. Yield: 19.8 g (37 mmol), 73.5% of theory; purity: 99.8% according to HPLC. Mixture of two atropisomers according to <sup>1</sup>H-NMR spectroscopy.

#### Example 2

2,6-Bis-o-tolyl-9,10-bis(2-(1-methyl-1-phenylethyl) phenyl)-anthracene

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Procedure analogous to Example 1b. Instead of 18.0 ml (150 mmol) of 2-bromotoluene, 41.3 g (150 mmol) of 1-bromo-2-(1-methyl-1-phenylethyl)benzene are used. Recrystallisation from dioxane. Sublimation p=1×10<sup>-5</sup> mbar, 5 T=360° C. Yield: 22.6 g (30 mmol), 60.5% of theory; purity: 99.9% according to HPLC. Atropisomerically pure according to <sup>1</sup>H-NMR spectroscopy.

#### Example 3

2,6-Bis-o-tolyl-9,10-bis(2-biphenyl)anthracene

Procedure analogous to Example 1b. Instead of 18.0 ml (150 mmol) of 2-bromotoluene, 25.9 ml (150 mmol) of 2-bromobiphenyl are used. Recrystallisation from chlorobenzene. Sublimation p= $1\times10^{-5}$  mbar, T=360° C. Yield: 27.1 g (41 mmol), 81.7% of theory; purity: 99.9% according to HPLC. Atropisomerically pure according to  $^{1}$ H-NMR spectroscopy.

#### Example 4

2,6-Bis-o-tolyl-9,10-bis(2-trimethylsilylphenyl)anthracene

Procedure analogous to Example 1b. Instead of 18.0 ml (150 mmol) of 2-bromotoluene, 34.4 g (150 mmol) of 2-trimethylsiylbromobenzene are used. Recrystallisation from dioxane. Sublimation p=1×10<sup>-5</sup> mbar, T=330° C. Yield: 21.9  $^{\,5}$  g (33 mmol), 66.8% of theory; purity: 99.9% according to

HPLC. At ropisomerically pure according to  $^1\mathrm{H}\text{-}\mathrm{NMR}$  spectroscopy.

### Example 5

The following compounds are prepared analogously to Examples 1b, 2, 3 and 4:  $\,$ 

Ex.	Bromide	Product
6	Br	

8 Br 
$$CF_3$$
  $F_3C$ 

Ex.	Bromide	Product
9	Br	

55

#### -continued

Ex.	Bromide	Product
11	Br F	F F
12	Br	

#### Example 13

2,6-Bisnaphth-1-yl-9,10-bis-o-tolylanthracene

a) 2,6-Bisnaphth-1-ylanthraquinone

A suspension of 28.7 g (100 mmol) of 2,6-dibromoan-thraquinone, 44.7 g (260 mmol) of 1-naphthylboronic acid, 89.2 g (420 mmol) of potassium phosphate, 1.8 g (6 mmol) of tri-o-tolylphosphine and 225 mg (1 mmol) of palladium(II) acetate in a mixture of 200 ml of dioxane, 400 ml of toluene and 500 ml of water is refluxed for 16 h. After cooling, the solid is filtered off with suction, washed three times with 100 ml of ethanol each time, dried in vacuo and subsequently recrystallised

 $^{45}~$  twice from chlorobenzene. Yield: 41.6 g (90 mmol), 90.3% of theory; purity: 99% according to NMR.

b) 2,6-Bisnaphth-1-yl-9,10-bis-o-tolylanthracene

Procedure analogous to Example 1b. Recrystallisation from NMP. Sublimation  $p=1\times10^{-5}$  mbar,  $T=375^{\circ}$  C. Yield: 22.2 g (36 mmol), 72.7% of theory; purity: 99.9% according to HPLC. Mixture of two atropisomers according to  $^{1}$ H-NMR spectroscopy.

# 55 Example 14

The following compounds are prepared analogously to Example 13:

Ex.	Bromide	Product
15	Br	

25

45

50

57

Example 18

2,6-Bis(9-(4-methylnaphthyl)anthracen-10-yl)-9,10-bis-o-tolylanthracene

a) 2,6-Bis-(9-(4-methylnaphthyl)anthracen-10-yl) anthraquinone

A suspension of 28.7 g (100 mmol) of 2,6-dibromoan-thraquinone, 133.3 g (300 mmol) of pinacolyl 10-(4-methyl-naphth-1-yl)anthracene-9-boronate, 96.7 g (600 mmol) of potassium fluoride and 1.2 g (1 mmol) of tetrakis-triphenylphosphinopalladium(0) in a mixture of 500 ml of ethylene glycol dimethyl ether, 200 ml of ethanol and 400 ml of water is refluxed for 36 h. After cooling, the solid is filtered off with suction, washed three times with 100 ml of water each time and three times with 100 ml of ethanol each time, dried in vacuo and subsequently recrystallised twice from o-dichlorobenzene. Yield: 66.9 g (79 mmol), 79.5% of theory; purity:  $^{40}$ 

b) 2,6-Bis-(9-(4-methylnaphthyl)anthracen-10-yl)-9, 10-bis-o-tolyl-anthracene

98% according to NMR.

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Procedure analogous to Example 1b. Instead of 19.4 g (50 mmol) of 2,6-bis-o-tolylanthraquinone, 42.1 g (50 mmol) of 2,6-bis(9-(4-methylnaphthyl) anthracen-10-yl)anthraquinone are used. After addition of the 2,6-bis(9-(4-methylnaphthyl)anthracen-10-yl)anthraquinone, 300 ml of toluene are added to the reaction mixture. Recrystallisation from o-dichlorobenzene. Sublimation p=1×10<sup>-5</sup> mbar, T 400° C. Yield: 27.5 g (28 mmol), 55.5% of theory; purity: 99.9% according to HPLC. Mixture of two atropisomers according to <sup>1</sup>H-NMR spectroscopy.

Example 19

2,6-Bis(p-tolylamino)-9,10-bis-o-tolylanthracene

a) 2,6-Dibromo-9,10-bis-o-tolylanthracene

Procedure analogous to Example 1b. Instead of 19.4 g (50 mmol) of 2,6-bis-o-tolylanthraquinone, 18.3 g (50 mmol) of 2,6-dibromoanthraquinone are used. Recrystallisation from toluene. Yield: 12.3 g (24 mmol), 47.6% of theory; purity: 97% according to NMR.

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b) 2,6-Bis (di-p-tolylaminophenyl-4-yl)-9,10-bis-o-

### tolylanthracene

A suspension of 51.6 g (100 mmol) of 2,6-dibromo-9,10-bis-o-tolylanthracene, 82.5 g (260 mmol) of di-p-tolylami-  $^{30}$  nophenyl-4-boronic acid, 89.2 g (420 mmol) of potassium phosphate, 1.8 g (6 mmol) of tri-o-tolylphosphine and 225 mg (1 mmol) of palladium(II) acetate in a mixture of 200 ml of dioxane, 400 ml of toluene and 500 ml of water is refluxed for  $^{35}$  16 h. After cooling, the solid is filtered off with suction, washed three times with 100 ml of water each time, washed

three times with 100 ml of ethanol each time, dried in vacuo, recrystallised five times from DMF and then sublimed in vacuo ( $p=1\times10^{-5}$  mbar,  $T=365^{\circ}$  C.). Yield: 68.7 g (76 mmol), 76.2% of theory; purity: 99.9% according to HPLC.

#### Example 20

The following compounds are prepared analogously to Example 19:

Ex.	Amine	Product
21	OH B OH	

60

Ex.	Amine	Product
22	OH B OH	
23	OH B OH	
24	OH B OH	

Ex.	Amine	Product
25	OH B OH	

Ex.	Amine	Product
27	OH B O	
28	OH B OH	

#### Example 29

2,6-Bisnaphth-1-yl-9-o-tolyl-10-2-biphenylanthracene

A 2-lithiobiphenyl solution in 200 ml of THF, prepared from 11.7 g (50 mmol) of 2-bromobiphenyl and 20 ml (50 mmol) of 2.5N n-butyllithium at -78° C., is added dropwise at -78° C. with vigorous stirring to a suspension of 46.1 g (100 mmol) of 2,6-bisnaphth-1-ylanthraquinone in 500 ml of 50 THF, and the mixture is stirred for a further 30 min. A 2-lithiotoluene solution in THF, prepared from 8.7 g (50 mmol) of 2-bromotoluene and 20 ml (50 mmol) of 2.5 N n-butyllithium at -78° C., is subsequently added to this suspension, and the mixture is stirred for a further 30 min. The reaction mixture is  $^{55}$  allowed to warm to room temperature, 30 ml of ethanol are added, and the solvent is removed in vacuo. The residue is taken up in 300 ml of DMF and warmed to 60° C., and 17.7 g (130 mmol) of tin(II) chloride are added in portions with vigorous stirring (note: exothermic reaction!). The mixture is subsequently stirred at 60° C. for a further 2 h. After cooling, 500 ml of 2.5 N hydrochloric acid are added, and the solid is filtered off with suction. The solid is washed three times with 100 ml of 2.5 N hydrochloric acid each time, three times with  $_{65}$  100 ml of water each time and three times with 100 ml of ethanol each time, dried in vacuo and subsequently recrystallised once from acetic acid and three times from dioxane.

Sublimation p=1×10<sup>-5</sup> mbar, T=345° C. Yield: 43.1 g (64 mmol), 64.0% of theory; purity: 99.9% according to HPLC. Mixture of two atropisomers according to <sup>1</sup>H-NMR spectroscopy

# Example 30

The following compounds are prepared analogously to Example 29:

		ampie 29.
Ex.	Bromides	Product
31	Br	
32	F Br	F
	Br	
33	Br	Br

Ex.	Bromides	Product
34	Br	

Example 35

#### Production of OLEDs

OLEDs are produced by a general process as described in WO 04/058911, which is adapted in individual cases to the particular circumstances (for example layer-thickness variation in order to achieve optimum efficiency or colour).

The results for various OLEDs are presented in Examples 36 to 48 below. Glass plates coated with structured ITO (indium tin oxide) form the substrates of the OLEDs. For improved processing, PEDOT (spin-coated from water; purchased from H. C. Starck, Goslar, Germany; poly(3,4-ethylene-dioxy-2,5-thiophene)) is applied directly to the substrate. The OLEDs always consist of the following layer sequence: substrate/PEDOT 20 nm/hole-injection layer (HIL1) 20 nm/hole-transport layer (HTM1) 20 nm/emission layer

(EML) 30 nm/electron-transport layer (ETM1) 20 nm and finally a cathode. The materials apart from PEDOT are thermally vapour-deposited in a vacuum chamber. The EML here always consists of a matrix material (host) and a dopant (guest), which is admixed with the host by co-evaporation.
 The cathode is formed by a 1 nm thin LiF layer and a 150 nm Al layer deposited on top. Table 2 shows the chemical structures of the materials used to construct the OLEDs.

These OLEDs are characterised by standard methods; for this purpose, the electroluminescence spectra, the efficiency (measured in cd/A), the power efficiency (measured in Im/W) as a function of the brightness, calculated from current/voltage/luminance characteristics (IUL characteristics), and the lifetime are determined

+. The lifetime is defined as the time after which the initial luminance has dropped from 1000 cd/m<sup>2</sup> to half.

Table 3 shows the results for some OLEDs (Examples 36 to 48). The comparative example used is host H1 in accordance with the prior art.

#### TABLE 2

Compounds used

HIL1

# TABLE 2-continued

Compounds used

HTM1

ETM1

H1 (comparison)

D1

TABLE 2-continued

Compounds used

TABLE 3

OLED results					
Example	EML	Max. efficiency (cd/A)	Voltage (V) at 1000 cd/m <sup>2</sup>	CIE	Lifetime (h) at 1000 cd/m <sup>2</sup>
36	H1 + 5% D1	9.9	5.7	x = 0.17/y = 0.33	4050
(comparison)				•	
37	H1 + 5% D2	3.4	6.2	x = 0.15/y = 0.13	1200
(comparison)				•	
38	Ex. $1 + 5\%$ D1	10.5	5.5	x = 0.17/y = 0.33	6100
39	Ex. $1 + 5\%$ D2	3.8	5.8	x = 0.15/y = 0.14	1800
40	Ex. $3 + 5\%$ D1	12.2	5.7	x = 0.17/y = 0.33	5800
41	Ex. $3 + 5\%$ D2	4.2	5.9	x = 0.15/y = 0.14	1600
42	Ex. $9 + 5\%$ D2	11.3	5.4	x = 0.17/y = 0.32	6300
43	Ex. 9 + 5% D2	3.9	5.8	x = 0.15/y = 0.15	2200
44	Ex. $17 + 5\%$ D3	11.5	5.5	x = 0.17/y = 0.33	7100
45	Ex. $17 + 5\%$ D3	3.5	5.9	x = 0.15/y = 0.14	2000
46	Ex. 9 + 5% Ex. 11	7.8	5.3	x = 0.15/y = 0.19	4800
47	Ex. 9 + 5% Ex. 19	8.0	5.6	x = 0.15/y = 0.24	5300
48	Ex. 17 + 7% Ex. 19	8.3	5.3	x = 0.16/y = 0.26	5600

The invention claimed is:

#### 1. A compound of formula (1)

Formula (1) 50  $\begin{bmatrix} R^{1} \\ R \end{bmatrix}_{p}$   $\begin{bmatrix} R^{1} \\ R \end{bmatrix}_{p}$ 

wherein

Ar is, identically or differently on each occurrence, phenyl, 1-naphthyl, 2-naphthyl, 2-anthryl, 9-anthryl, 2-phenan-

threnyl, 3-phenanthrenyl or 9-phenanthrenyl each optionally substituted by one or more radicals R';

R is, identically on each occurrence, F,  $Si(R^2)_3$ ; — $N(Ar^1)_2$ ; a straight-chain alkyl or alkoxy group having 1 to 4 C atoms or a branched alkyl group having 3 to 5 C atoms, each of which may be substituted by one or more radicals  $R^2$ , where one or more H atoms may be replaced by F, or a phenyl group;

R<sup>1</sup>

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are, identically or differently on each occurrence, F; Cl; Br; I; CN;  $N(Ar^1)_2$ ;  $C(=O)Ar^1$ ;  $P(Ar^1)_2$ ;  $P(=O)(Ar^1)_2$ 

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—S—, — $N(R^2)$ —, or — $CONR^2$ — and wherein one or more H atoms of said straight-chain alkyl, alkoxy or thioalkoxy group or said branched or cyclic alkyl, alkoxy or thioalkoxy group are optionally replaced by F, Cl, Br, I, CN, or  $NO_2$ ; an aromatic or hetero-aromatic ring system having 5 to 30 aromatic ring atoms optionally substituted by one or more radicals  $R^2$ ; or an aryloxy or heteroaryloxy group having 5 to 24 aromatic ring atoms optionally substituted by one or more radicals  $R^2$ ; or a combination of two, three, four or five substituents  $R^1$ ;

Ar<sup>1</sup> is, identically or differently on each occurrence, an aromatic or heteroaromatic ring system having 5 to 30 aromatic ring atoms optionally substituted by one or more non-aromatic radicals R<sup>1</sup> and wherein two radicals Ar<sup>1</sup> are optionally connected to one another by a single 15 bond or an O. S. N(R<sup>2</sup>), or C(R<sup>2</sup>), group:

bond or an O, S, N(R<sup>2</sup>), or C(R<sup>2</sup>)<sub>2</sub> group;
R<sup>2</sup> is, identically or differently on each occurrence, H or a hydrocarbon radical having 1 to 20 C atoms, wherein said hydrocarbon radical is aliphatic, aromatic, or a combination of aliphatic and aromatic and is optionally substituted by F and wherein two or more radicals R<sup>2</sup> optionally define a mono- or polycyclic, aliphatic or aromatic ring system with one another;

n is 0;

p is 0;

with the proviso that if R<sup>1</sup> contains a benzimidazole group, 25 it is not bonded to Ar.

2. The compound of claim 1, wherein both Ar are identical.

3. The compound of claim 1, wherein said compound has a formula selected from the group consisting of formulae (2), (3), (4), and (5)

Formula (2)  $\begin{bmatrix} \mathbb{R}^1 \\ \mathbb{R}^1 \\ \mathbb{R}^1 \end{bmatrix}_n$  Formula (3)

$$\begin{bmatrix} R^{1} \\ R \end{bmatrix}_{n}$$

$$\begin{bmatrix} R^{1} \\ R \end{bmatrix}_{n}$$

$$\begin{bmatrix} R^{1} \\ R \end{bmatrix}_{n}$$

-continued Formula (4)

R
R
R
R
R
R
P

Formula (5)  $\begin{bmatrix} R \\ p \end{bmatrix}_{p}$   $\begin{bmatrix} R^{1} \\ n \end{bmatrix}_{n}$   $\begin{bmatrix} R \\ p \end{bmatrix}_{p}$ 

wherein q is 0, 1, 2, 3, 4, or 5.

4. A process for preparing the compound of claim 1 comprising (1) reacting an anthraquinone substituted in the 2,6-50 position by chlorine, bromine, iodine, or a sulfonic acid derivative with a boronic acid derivative of the group Ar with palladium catalysis to form a first intermediate, (2) reacting said first intermediate with a corresponding ortho-substituted organometallic phenyl derivative to form a second interme-55 diate, and (3) reducing said second intermediate.

5. An organic electronic device selected from the group consisting of organic electroluminescent devices, organic field-effect transistors, organic thin-film transistors, organic light-emitting transistors, organic integrated circuits, organic solar cells, organic field-quench devices, organic photo receptors, light-emitting electrochemical cells and organic laser diodes, comprising at least one compound of claim 1.

**6.** An organic electroluminescent device comprising at least one compound of claim **1**.

7. The organic electroluminescent device of claim 6, comprising an anode, a cathode, and at least one emitting layer, and optionally comprising further layers selected from the

group consisting of hole-injection layers, hole-transport layers, hole-blocking layers, electron-transport layers, electron-injection layers, and/or charge-generation layers.

- 8. The organic electroluminescent device of claim 7, wherein said organic electroluminescent device comprises a 5 host material comprising a host and a dopant wherein said host material comprises the compound of claim 1 and is used as a fluorescent emitter and/or as an electron-transport material and/or as a hole-blocking material.
- 9. The organic electroluminescent device of claim 8, 10 wherein said dopants are selected from the group consisting of aromatic anthraceneamines, aromatic anthracenediamines, aromatic pyrenediamines, monostyrylamines, distyrylamines, tristyrylamines, tetrastyrylamines, styrylphosphines, styryl ethers, and ary- 15 lamines.
- 10. The organic electroluminescent device of claim 7, wherein said compound of claim 1 is used as an emitting compound in an emitting layer and/or as a hole-transport material.
- 11. The organic electroluminescent device of claim 10, wherein said hole-transport material is comprised in a hole-transport layer or a hole-injection layer.
- 12. The organic electroluminescent device of claim 11, wherein R is an  $N(Ar^1)_2$  group and/or  $R^1$  is an  $N(Ar^1)_2$  group. 25
- 13. The compound of claim 1, wherein Ar is a group of Formula (9), Formula (10) or Formula (11)

 $\mathbb{R}^d$   $\mathbb{R}^c$ 

**78** 

-continued

Formula (10)

Formula (11)

$$\mathbb{R}^c$$

wherein  $R^c$  and  $R^d$  are defined as  $R^1$ , with the proviso that  $R^c$  in Formula (9) is defined as R.

Formula (9) 30 differently on each occurrence, F,  $Si(R^2)_3$ , a straight-chain alkyl or alkoxy group having 1 to 4 C atoms or a branched alkyl group having 3 to 5 C atoms, each of which may be substituted by one or more radicals  $R^2$ , where one or more H atoms may be replaced by F.

\* \* \* \* \*



专利名称(译)	用于有机电致发光器件的材料		
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# 摘要(译)

本发明涉及蒽衍生物,其在有机电致发光器件中的用途,以及包含这些化合物的有机电致发光器件。

$$\begin{bmatrix} \mathbb{R}^1 \\ \mathbb{R}^1 \end{bmatrix}_p$$

$$\begin{bmatrix} \mathbb{R}^1 \\ \mathbb{R}^1 \end{bmatrix}_p$$

$$\begin{bmatrix} \mathbb{R}^1 \\ \mathbb{R}^1 \end{bmatrix}_p$$